

# TMD3719 ALS/Color and Proximity Sensor

## **General Description**

The TMD3719 features ambient light and color (RGB) sensing, flicker detection and proximity detection. The device integrates three IR VCSELs and an advanced VCSEL driver within a low-profile 6.35mm x 3.00mm x 1.00mm package.

The ambient light and color sensing function provides six concurrent ambient light sensing channels: Red, Green, Blue, Clear, Leakage and Wideband. The RGBL and Clear channels have a UV/IR blocking filter. This architecture accurately measures ambient light and enables the calculation of illuminance, chromaticity, and color temperature to manage display appearance.

The device integrates direct detection of ambient light flicker for 4 selectable frequency bins. Flicker detection is executed in parallel with ambient light and color sensing. The flicker detection engine can also buffer data for calculating other flicker frequencies externally.

The proximity function synchronizes IR emission and detection to sense nearby objects. The architecture of the engine features self-maximizing dynamic range, ambient light subtraction, advanced crosstalk cancelation, and interrupt-driven I<sup>2</sup>C communication. Sensitivity, power consumption, and noise can be optimized with adjustable IR VCSEL timing and power. The proximity engine recognizes detect/release events and produces a configurable interrupt whenever the proximity result crosses upper or lower threshold settings.

Ordering Information and Content Guide appear at end of datasheet.

## **Key Benefits & Features**

The benefits and features of TMD3719 are listed below:

Benefits	Features
Improved Lux Accuracy for ALS Behind OLED	<ul><li>High Sensitivity</li><li>Leakage Channel</li></ul>
Minimized Display Distortion for Proximity Behind OLED	<ul> <li>Proximity Function Synchronized with Display</li> <li>Multiple VCSEL Emitters to Lower the Optical Power Density</li> </ul>

Figure 1: Added Value of Using TMD3719



## Applications

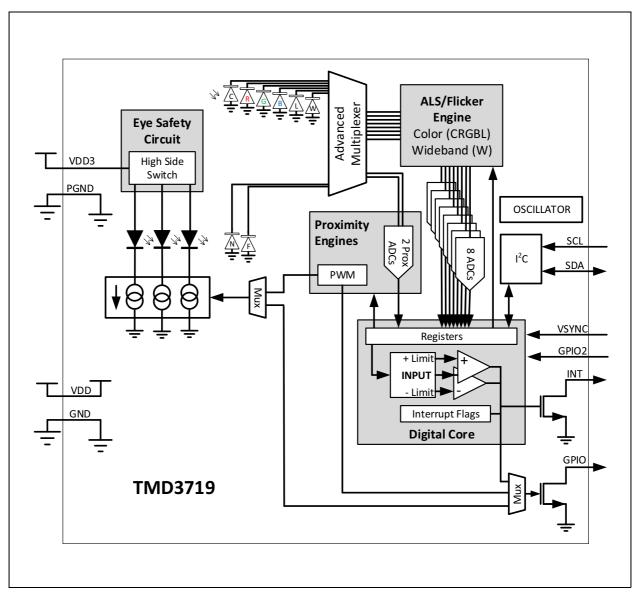
TMD3719 integrates multiple applications within one device. The applications for TMD3719 include:

- Brightness management for displays
- Color management for displays
- Camera image processing
- Flicker-immune camera operation
- Touch screen disable

## **Block Diagram**

The functional blocks of this device are shown below:

Figure 2: Functional Blocks of TMD3719



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# **Pin Assignments**

## Device pinout is described below.

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Figure 3:
Pin Diagram of TMD3719
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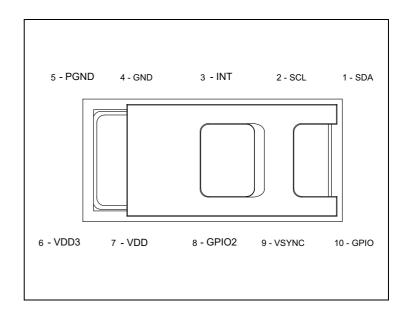


Figure 4: Pin Description of TMD3719

Pin Number	Pin Name	Description
1	SDA	I <sup>2</sup> C serial data I/O terminal
2	SCL	I <sup>2</sup> C serial clock terminal
3	INT	Interrupt. Open-drain output plus supports additional output options.
4	GND	Ground. All voltages are referenced to GND/PGND, and both ground pins must be connected to ground.
5	PGND	Ground. All voltages are referenced to GND/PGND, and both ground pins must be connected to ground.
6	VDD3	Supply voltage (3.3V)
7	VDD	Supply voltage (1.8V)
8	GPIO2	General purpose input
9	VSYNC	VSYNC input
10	GPIO	Open-drain general purpose input/output



# Absolute Maximum Ratings

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

All voltages with respect to GND/PGND. Device parameters are guaranteed at  $V_{DD} = 1.8$  V and  $T_A = 25$ °C unless otherwise noted.

Figure 5: Absolute Maximum Ratings

Symbol	Parameter	Min Max		Units	Comments					
	El	ectrical	Paramet	ers						
V <sub>DD</sub>	Supply Voltage to GND	-0.3	1.98							
V <sub>DD3</sub>	Emitter Supply Voltage to GND	-0.3 3.6		V						
V <sub>IO</sub>	Digital I/O Terminal Voltage	-0.3	3.6							
I <sub>IO</sub>	Digital Output Terminal Current	-1	20							
I <sub>SINK</sub>	VCSEL Current <sup>(1)</sup>	0 10		mA	The VCSEL current setting should not exceed 10mA for any of the VCSELs to maintain Class 1 laser safety.					
	Ele	ctrostat	ic Disch	arge						
I <sub>SCR</sub>	Input Current (latch-up immunity)	± 100		mA	Class II JEDEC JESD78D					
ESD <sub>HBM</sub>	HBM Electrostatic Discharge	±2000		V	JEDEC/ESDA JS-001-2017					
ESD <sub>CDM</sub>	CDM Electrostatic Discharge	± 5	500	V	JEDEC JESD22-C101F					
	Temperature Ranges and Storage Conditions									
T <sub>STRG</sub>	Storage Temperature Range	-40	85	°C						
T <sub>A</sub>	Operating Temperature Range <sup>(2)</sup>	-30	85							

#### Note(s):

1. This ensures the maximum optical power is <12mW at 940nm  $\pm 10$ nm.

2. While the device is operational across the temperature range, functionality will vary with temperature.

# Figure 6:

## **Recommended Operating Conditions**

Symbol	Parameter	Min	Тур	Мах	Units
V <sub>DD</sub>	Supply Voltage	1.7	1.8	1.98	V
V <sub>DD3</sub>	Emitter Supply Voltage	2.9	3.3	3.6	V
I <sub>SINK</sub>	VCSEL Current	10	10	10	mA



# **Electrical Characteristics**

All limits are guaranteed. The parameters with min and max values are guaranteed with production tests or SQC (Statistical Quality Control) methods.

Figure 7:

Electrical Characteristics of TMD3719, V<sub>DD</sub> = 1.8V, V<sub>DD3</sub> = 3.3V, T<sub>A</sub> = 25°C (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		Active ALS State <sup>(2)</sup> (PON=AEN=1, WEN=PEN=0)		380	460	
	Supply current <sup>(1)</sup>	Active Proximity State (PON=PEN=1, AEN=0)		600	700	μA
I <sub>DD</sub>	Supply current W	ldle State <sup>(3)</sup> (PON=1, AEN=PEN=0)		125	150	μΛ
		Sleep State <sup>(4)</sup> (PON = 0)		0.7	5.0	
V <sub>OL</sub>	INT, SDA, GPIO output low voltage	3mA sink current			0.36	V
I <sub>LEAK</sub>	Leakage current, SDA, SCL, INT		-5		5	μΑ
V <sub>IH</sub>	SCL, SDA, VSYNC input high voltage		1.26			V
V <sub>IL</sub>	SCL, SDA, VSYNC input low voltage				0.54	V
T <sub>WAKEUP</sub>	Time from sleep state exit to proximity engine ready <sup>(5)</sup>		0.5			ms
T <sub>ACTIVE</sub>	Time from power-on to ready for receiving I <sup>2</sup> C commands <sup>(5)</sup>		1.5			ms

#### Note(s):

1. Values are shown at the VDD pin and do not include current through the VDD3 pin.

2. This parameter indicates the supply current during periods of ALS integration. The ALS gain setting will have an effect on the active supply current. The ALS gain setting for this parameter is 2x.

3. Idle state occurs when PON=1 and all functions are not enabled.

4. Sleep state occurs when PON = 0 and  $I^2C$  bus is idle. If Sleep state has been entered as the result of operational flow, SAI = 1, PON will remain high.

5. Not production tested. Specified by design and characterization.



# **Optical Characteristics**

All limits are guaranteed. The parameters with min and max values are guaranteed with production tests or SQC (Statistical Quality Control) methods. Device parameters are guaranteed with  $V_{DD} = 1.8V$ ,  $V_{DD3} = 3.3V$  and  $T_A = 25^{\circ}C$  unless otherwise noted.

Figure 8:

ALS/Color Characteristics of TMD3719, ALS Gain = 512x, Integration Time = 10.8ms (unless otherwise noted)

Parameter	Conditions	Min	Тур	Max	Unit
Dark ADC count value <sup>(1)</sup>	Ee = 0μW/cm <sup>2</sup> ALS gain: 4096x Integration time: 22ms	0	0	3	counts
	2x	0.0032	0.0041	0.0049	
	4x	0.0068	0.0083	0.0095	
	8x	0.0138	0.0164	0.0176	
	16x	0.0270	0.0317	0.0345	
	32x	0.050	0.061	0.067	
ALS gain ratios	64x	0.105	0.124	0.134	
	128x	0.217	0.249	0.267	
	256x	0.454	0.498	0.526	
	1024x	1.85	2.02	2.50	
	2048x	3.2	4.1	10.0	
	4096x	5.0	9.0	18.0	
Clear channel irradiance responsivity <sup>(1)</sup>	White LED, 3000K <sup>(2)</sup>	559	657	756	counts/
Wideband channel irradiance responsivity <sup>(1)</sup>	White LLD, SOUCK		332		μW/cm <sup>2</sup>
Lux accuracy <sup>(3)</sup>	x accuracy <sup>(3)</sup> White LED, 3000K Integration time: 100ms		100	115	%
ADC noise <sup>(4)</sup>	White LED, 3000K ALS gain: 1024x Integration time: 355ms		0.025		%

Parameter	Conditions	Min	Тур	Max	Unit
	White LED, 3000K	52	62	72	
Red/Clear channel ratios	Blue LED, $\lambda_D = 465 \text{nm}^{(5)}$	1	7	13	
	Red LED, $\lambda_D = 615 \text{nm}^{(6)}$	80	97	113	
	White LED, 3000K	21	31	41	
Green/Clear channel ratios	Green LED, $\lambda_D = 525 \text{nm}^{(7)}$	63	76	88	
	Red LED, $\lambda_D = 615$ nm	5	8	12	%
	White LED, 3000K	7	18	30	
Blue/Clear channel ratios	Blue LED, $\lambda_D = 465$ nm	74	88	103	
	Red LED, $\lambda_D = 615$ nm	Red LED, $\lambda_D = 615$ nm 0		12	
Leakage/Clear channel ratio	White LED, 3000K	0	1	5	
Wideband/Clear channel ratio	White LED, 3000K	36	48	60	
Wideband/IR channel ratio	IR LED = 940nm <sup>(8)</sup>	7	13	18	

#### Note(s):

1. ALS output values (ADATAX) are divided by 4 to account for the output having 2 sub-LSBs.

2. The White LED is an InGaN light-emitting diode with integrated phosphor that has a correlated color temperature = 3000K.

3. Lux accuracy is an illuminance estimated using the red, green, blue, and clear channels and is not 100% production tested.

4. ADC noise is calculated as the standard deviation of 1000 data samples divided by full scale and is not 100% production.

5. The Blue LED is an InGaN light-emitting diode with the following characteristics: dominant wavelength  $\lambda_D$  = 465nm, spectral halfwidth  $\Delta\lambda \frac{1}{2}$  = 22nm.

6. The Red LED is an AllnGaP light-emitting diode with the following characteristics: dominant wavelength  $\lambda_D = 615$  nm, spectral halfwidth  $\Delta\lambda$ <sup>1</sup>/<sub>2</sub> = 15 nm.

7. The Green LED is an InGaN light-emitting diode with the following characteristics: dominant wavelength  $\lambda_D$  = 525nm, spectral halfwidth  $\Delta\lambda$ <sup>1</sup>/<sub>2</sub> = 35nm.

8. The IR LED is an AIGaAs light-emitting diode with the following characteristics: peak wavelength  $\lambda P = 940$ nm, spectral halfwidth  $\Delta \lambda 1/2 = 42$ nm.

## Figure 9: Proximity Characteristics of TMD3719

# 19 Conditions Min Typ Max Unit 0.(1x)(1x) (x s set to 10mA<sup>(5)</sup>) (EN = 4 (64µs) 2 (3pulses) 75 100 125 %

Parameter	Conditions	Min	Тур	Max	Unit
Near Response, Relative Variation <sup>(1), (4)</sup>	PGAIN = 0 (1x) All 3 ISINKs set to $10mA^{(5)}$ PPULSE_LEN = 4 (64µs) PPULSE = 2 (3pulses) d= 50mm round target 84mm target distance After electrical calibration	75	100	125	%
Far Response, Relative Variation <sup>(1), (4)</sup>	PGAIN = 0 (1x) All 3 ISINKs set to $10mA^{(5)}$ PPULSE_LEN = 4 (64 $\mu$ s) PPULSE = 2 (3pulses) d= 50mm round target 84mm target distance After electrical calibration	80	100	120	%
Near/Far Ratio Response, Relative Variation <sup>(1)</sup>	PGAIN = 0 (1x) All 3 ISINKs set to $10mA^{(5)}$ PPULSE_LEN = 4 (64µs) PPULSE = 2 (3pulses) d= 50mm round target 84mm target distance After electrical calibration	87.5	100	112.5	%
Near Response, Absolute <sup>(2)</sup>	PGAIN = 0 (1x) All 3 ISINKs set to $10mA^{(5)}$ PPULSE_LEN = 3 (32µs) PPULSE = 0 (1pulse) POFFSET = 0 100mm x 100mm, 90% reflective Kodak gray card 100mm target distance	5338	7117	8897	counts
Far Response, Absolute <sup>(2)</sup>	PGAIN = 0 (1x) All 3 ISINKs set to $10mA^{(5)}$ PPULSE_LEN = 3 (32µs) POULSE = 0 (1pulse) POFFSET = 0 100mm x 100mm, 90% reflective Kodak gray card 100mm target distance	5419	6774	8129	counts

Parameter	Conditions	Min	Тур	Max	Unit
Noise/Signal <sup>(3)</sup>	PGAIN = 0 (1x) All 3 ISINKs set to $10mA^{(5)}$ PPULSE_LEN = 2 (16 $\mu$ s) PPULSE = 7 (8 $\mu$ s) POFFSET = 0			2	%

### Note(s):

1. Production tested result is the average of 5 readings expressed relative to a calibrated response.

2. Representative result by characterization. This characterization result does not include the VCSEL output power drift over the life of the product.

3. Production tested result is the range of 10 readings divided by the average response.

4. Production test does not include the VCSEL output power drift over the life of the product. The VCSEL output power drift will stay within ±1dB of the initial output power for standard device operation using all 3 VCSELs.

5. Use ISINK\_RELEASE = ISINK\_DETECT = 3 (2x), ISINK0 = 4 (5mA) and ISINK1 = ISINK2 = 5 (5mA) to set all 3 VCSELs with 10mA drive current.



# **Timing Characteristics**

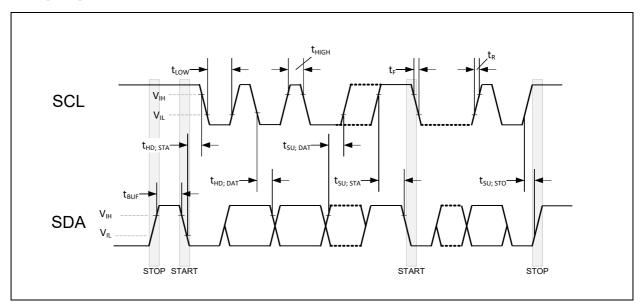
The timing parameters are specified by design and characterization and are not production tested unless otherwise noted. All parameters are measured with  $V_{DD} = 1.8V$ ,  $V_{DD3} = 3.3V$  and  $T_A = 25^{\circ}C$  unless otherwise noted.

## Figure 10: I<sup>2</sup>C Timing Characteristics of TMD3719

Symbol	Parameter	Min	Тур	Max	Unit
f <sub>SCL</sub>	I <sup>2</sup> C clock frequency	0		400	kHz
t <sub>BUF</sub>	Bus free time between start and stop condition	1.3			
t <sub>HS;STA</sub>	Hold time after (repeated) start condition. After this period, the first clock is generated	0.6			
t <sub>SU;STA</sub>	Repeated start condition setup time	0.6			μs
t <sub>SU;STO</sub>	Stop condition setup time	0.6			
t <sub>LOW</sub>	SCL clock low period	1.3			
t <sub>HIGH</sub>	SCL clock low period	0.6			
t <sub>HD;DAT</sub>	Data hold time	0			
t <sub>SU;DAT</sub>	Data setup time	100			ns
t <sub>F</sub>	Clock/data fall time			300	115
t <sub>R</sub>	Clock/data rise time			300	

### Figure 11:

**Timing Diagram for TMD3719** 



# Figure 12:

## Functional Timing Characteristics of TMD3719

Symbol	Parameter	Min	Тур	Max	Unit
f <sub>OSC</sub>	Oscillator clock frequency <sup>(1)</sup>	357	369	380	kHz
t <sub>OSL</sub>	Oscillator clock cycle <sup>(1)</sup>	2.63	2.71	2.80	μs
t <sub>(PROX ADC)</sub>	Proximity ADC conversion time		20		μs

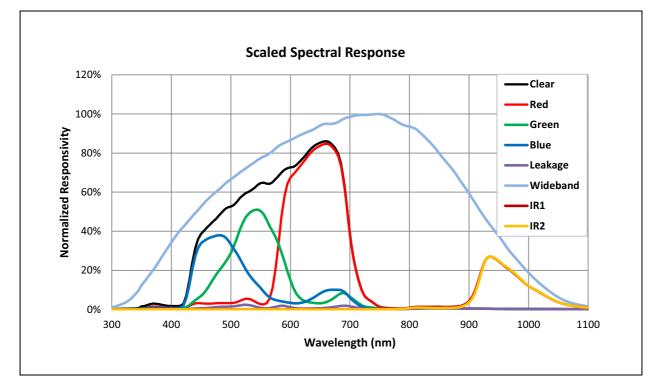
### Note(s):

1. 100% production tested.



# Typical Operating Characteristics

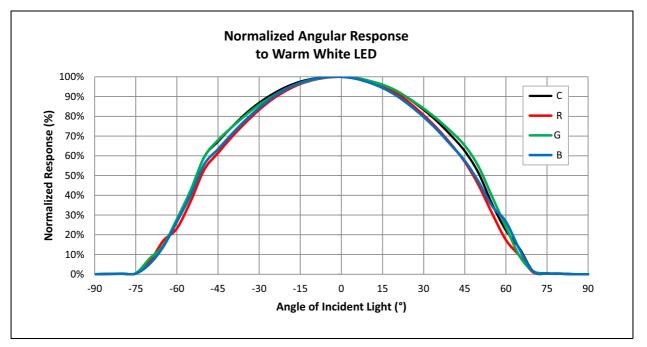
Figure 13: Spectral Responsivity



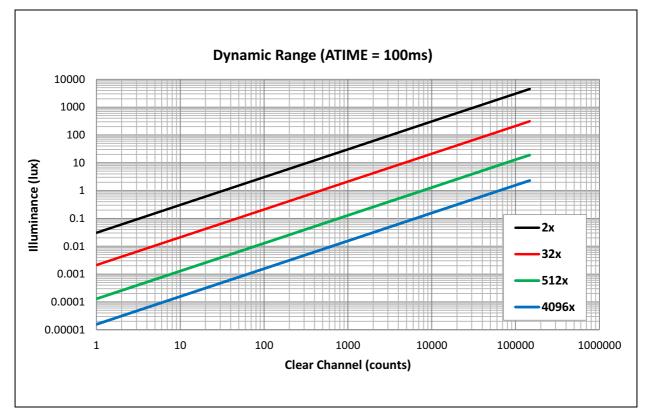
#### Note(s):

1. The spectral responsivities shown in the figure are scaled based on the photodiode area of each channel. The scaling factors used to generate this figure are (relative to CLEAR): 1.25 for Leakage, 2.5 for Wideband, 0.18 for IR1 and 0.25 for IR2. Once scaled, the responsivities are normalized.





## Figure 15: Illuminance (Lux) vs. Counts (Clear Channel)



## **Detailed Description**

Upon power-up, POR, the device initializes. During initialization (maximum of 1.5ms), the device will deterministically send NAK on  $I^2C$  and cannot accept  $I^2C$  transactions. All communication with the device must be delayed, and all outputs from the device must be ignored including interrupts. After initialization, the device enters the SLEEP state. In this operational state the internal oscillator and other circuitry are not active, resulting in ultra-low power consumption. If an  $I^2C$  transaction occurs during this state, the  $I^2C$  core wakes up temporarily to service the communication. Once the Power ON bit, PON, is enabled, the device enters the IDLE state in which the internal oscillator and attendant circuitry are active, but power consumption remains low. Whenever a function is enabled (PEN | AEN = 1) the device exits the IDLE state. If all functions are disabled (PEN = 0 & AEN = 0), the device returns to the IDLE state.

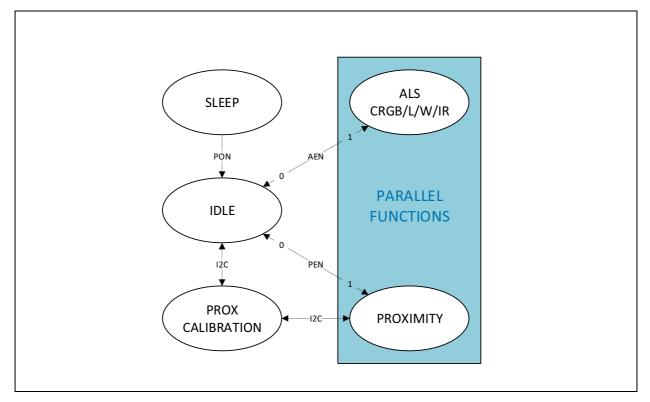
As depicted in Figure 16 the proximity and CRGBLW color sensing functions operate in parallel when enabled (PEN | AEN = 1). In addition, when proximity calibration is requested, it will temporarily disable the proximity function. Each function is individually configured (e.g. gain, ADC integration time, wait time, persistence, thresholds, etc.).

If Sleep after Interrupt is enabled (SAI = 1 in register 0x96), the state machine will enter SLEEP when an interrupt occurs. Entering SLEEP does not automatically change any of the register settings (e.g. PON bit is still high, but the normal operational state is over-ridden by SLEEP state). SLEEP state is terminated when the SAI\_ACTIVE bit is cleared (the status bit is in register 0xBE and the clear status bit is in register 0xF6).



**State Machine Diagrams** 

## Figure 16: Simplified State Diagram



## I<sup>2</sup>C Protocol

The device uses I<sup>2</sup>C serial communication protocol for communication. The device supports 7-bit chip addressing and both standard and full-speed clock frequency modes. Read and Write transactions comply with the standard set by Philips (now NXP). For a complete description of the I<sup>2</sup>C protocol, please review the NXP I<sup>2</sup>C design specification.

Internal to the device, an 8-bit buffer stores the register address location of the desired byte to read or write. This buffer auto-increments upon each byte transfer and is retained between transaction events (I.e. valid even after the master issues a STOP command and the I<sup>2</sup>C bus is released). During consecutive Read transactions, the future/repeated I<sup>2</sup>C Read transaction may omit the memory address byte normally following the chip address byte; the buffer retains the last register address +1.

All 16-bit fields have a latching scheme for reading and writing. In general it is recommended to use I<sup>2</sup>C bursts whenever possible, especially in this case when accessing two bytes of one logical entity. When reading these fields, the low byte must be read first, and it triggers a 16-bit latch that stores the 16-bit field. The high byte must be read immediately afterwards. When writing to these fields, the low byte must be written first, immediately followed by the high byte. Reading or writing to these registers without following these requirements will cause errors.

A Write transaction consists of a START, CHIP-ADDRESSWRITE, REGISTER-ADDRESS WRITE, DATA BYTE(S), and STOP. Following each byte (9TH clock pulse) the slave places an ACKNOWLEDGE/NOT- ACKNOWLEDGE (ACK/NACK) on the bus. If NACK is transmitted by the slave, the master may issue a STOP.

A Read transaction consists of a START, CHIP-ADDRESSWRITE, REGISTER-ADDRESS, RESTART, CHIP-ADDRESSREAD, DATA BYTE(S), and STOP. Following all but the final byte the master places an ACK on the bus (9TH clock pulse). Termination of the Read transaction is indicated by a NACK being placed on the bus by the master, followed by STOP.

## **Register Overview**

The device is controlled and monitored by registers accessed through the I<sup>2</sup>C serial interface. These registers provide device control functions and are read to determine device status and acquire device data.

## **Register Map**

The register set is summarized in Figure 17. The values of all registers and fields that are listed as reserved or are not listed must not be changed at any time. Bits 7 (MSB) through 0 (LSB) are shown in the last columns of the table. The power-on reset values of each bit are indicated in these columns. Two-byte fields are always latched with the low byte followed by the high byte.

The functions column illustrates the purpose of each register by highlighting the function associated to each bit. The bits are shown from MSB (bit7) to LSB (bit0). **GRAY** indicates fields apply independent of one function or apply to all functions, **GREEN** indicates fields that are pertinent to ALS/color sensing and flicker detection and **BLUE** indicates fields that are pertinent to proximity detection. **WHITE** fields are reserved and their values must not be changed at any time.

Figure 17: Register Map

Addr	Name	Туре	Description	7	6	5	4	3	2	1	0	Reset
0x2E					0000000						0x00	
0x2F	AILT	R/W	ALS interrupt low threshold		0000000					0x00		
0x30					0000000						0x00	
0x31				0000000						0x00		
0x32	AIHT	R/W	ALS interrupt high threshold	00000000						0x00		
0x33					0000000					0x00		
0x34	PILTO	R/W	Proximity interrupt low			C	0000	000	C			0x00
0x35	TIETO	17, 17	threshold zero			C	0000	000	0			0x00
0x36	PIHTO	R/W	Proximity interrupt high					000				0x00
0x37		10,00	threshold zero			C	0000	000	C			0x00
0x38	PILT1	R/W	Proximity interrupt low					000				0x00
0x39			threshold one	0000000					0x00			
0x3A	PIHT1	R/W	Proximity interrupt high	0000000				0x00				
0x3B		10,00	threshold one			C	0000	000	0			0x00

Addr	Name	Туре	Description	7	6	5	4	3	2	1	0	Reset
0x3C	PILTR	R/W	Proximity interrupt low 00000000 threshold ratio							0x00		
0x3D	PILIK	K/ VV	threshold ratio	0000000					0x00			
0x3E	PIHTR	R/W	Proximity interrupt high	0000000						0x00		
0x3F	FILLIN	TV VV	threshold ratio	00000000					0x00			
0x40	FD_CFG0	R/W	Flicker detection configuration zero		000		0	0	0	0	1	0x01
0x41	FD_CFG1	R/W	Flicker detection configuration one		000			C	0000	)		0x00
0x42	FD_CFG2	R/W	Flicker detection configuration two		000			C	0000	)		0x00
0x43	FD_CFG3	R/W	Flicker detection configuration three		000			C	0000	)		0x00
0x44	FD_CFG4	R/W	Flicker detection 000 00000 configuration four				00000			0x00		
0x45	FD_CFG5	R/W	Flicker detection 11111110				1111110			0xFE		
0x47	FD_CFG7	R/W	Flicker detection configuration seven	000000 01			1	0x01				
0x48	FD_CFG8	R/W	Flicker detection configuration eight			(	0110	011	1			0x67
0x4F 0x50	SYNC_DELAY	R/W	Synchronized delay				)000 )000					0x00 0x00
0x53	VSYNC_CFG0	R/W	Vertical sync configuration zero		00	01		0	0	0	0	0x10
0x54	VSYNC_CFG1	R/W	Vertical sync configuration one	0	0			010	000			0x10
0x56	VSYNC_CFG2	R/W	Vertical sync configuration     00000000       two     00000000		0000000			0x00				
0x57	VSYNC_CFG3	R/W	Vertical sync configuration three 00000000			0000000			0x00			
0x69	CALIB	R/W	Calibration start 0000000 0			0	0x00					
0x6A	CALIBCFG0	R/W	Calibration configuration zero	o 0 0 00 0 000				0x00				
0x6B	CALIBCFG1	R/W	Calibration configuration one	ion one 0 0 0 0 0 1 100				0x0C				
0x6C	CALIBCFG2	R/W	Calibration configuration two	000 00000			0x00					
0x6D	CALIBSTAT	R/W	Calibration status	00000 0 0 0			0x00					
0x80	ENABLE	R/W	Enable device states				0	0x00				

Addr	Name	Туре	Description	7	7 6 5 4 3 2 1 0		Reset				
0x81	MEAS_MODE0	R/W	Measurement mode zero	0 0 00 00 0 0			0x00				
0x82	MEAS_MODE1	R/W	Measurement mode one	0 0 000 000				0x00			
0x83	TRIGGER_MODE	R/W	Trigger Mode	0 000 0 000				0x00			
0x84	ATIME	R/W	ALS integration time			000	0000	0			0x00
0x85	ASTEP	R/W	ALS integration step				1111	- C.			0xFF
0x86	ASTE	10,00	The integration step			000	0001	1			0x03
0x87	PTIME	R/W	Proximity time			000	0000	0			0x00
0x88	WTIME	R/W	Wait time			000	0000	0			0x00
0x89	MOD_GAIN_0_1	R/W	Modulator zero and one gain		00	00		00	000		0x00
0x8A	MOD_GAIN_2_3	R/W	Modulator two and three gain		00	00		00	000		0x00
0x8B	MOD_GAIN_4_5	R/W	Modulator four and five gain		00	00		00	000		0x00
0x8C	MOD_GAIN_6_7	R/W	Modulator six and seven gain	0000 0000			0x00				
0x8D	AGC_ENABLE	R/W	AGC enable	0 0 0 0 0 0 0 0			0x00				
0x90	AUXID	R	Auxiliary identification	00000011			0x03				
0x91	REVID	R	Revision identification	00010011			0x13				
0x92	ID	R	Device identification			010	0000	0			0x40
0x93	CFG0	R/W	Configuration zero	0	0	100	)		000		0x20
0x96	CFG3	R/W	Configuration three	0	0	0 0		1	111		0x0F
0x97	CFG4	R/W	Configuration four		00	00		00	000		0x00
0x9A	PERS	R/W	Persistence configuration		00	01		00	001		0x11
0x9B	CFG8	R/W	Configuration eight	1	0		000	0000	)		0x80
0x9C	CFG9	R/W	Configuration nine	0	0		000	0000	)		0x00
0x9D	CFG10	R/W	Configuration ten	11 11 0010			0xF2				
0x9E	CFG11	R/W	Configuration eleven	0 1 000000			0x40				
0x9F	CFG12	R/W	Configuration twelve	00000 000			0x00				
0xA4	AZ_CONFIG	R/W	Autozero configuration	1111111			0xFF				
0xA7	CFG20	R/W	Configuration twenty	000 0 0000			0x00				
0xAA	PCFG1	R/W	Proximity configuration one	0 000 0 000			0x00				
0xAB	PCFG2	R/W	Proximity configuration two	00 00 0000			0x00				
0xAC	PCFG3	R/W	Proximity configuration three	0000 0000			0x00				
				-							

Addr	Name	Туре	Description	7	6	5	4	3	2	1	0	Reset
0xAD	PCFG4	R/W	Proximity configuration four		00	00	•	1	0	1	0	0x0A
0xAE	PCFG5	R/W	Proximity configuration five	00001111					0x0F			
0xAF	PCFG6	R/W	Proximity configuration six	0 000 0 0 0					0x00			
0xB0	PCFG7	R/W	Proximity configuration seven		000		0	0		001		0x01
0xB1	POFFSET0	R/W	Proximity offset zero				0000					0x00
0xB2	TOTISETO	10,00	Troximity onset 2010			(	0000	000	0			0x00
0xB3	PXAVG	R/W	Proximity average			(	0000	000	0			0x00
0xB4	TANG	10, 10				(	0000	000	0			0x00
0xB5	PBSLN	R/W	Proximity baseline				0000					0x00
0xB6	TUSEN	10, 10	Troximity baseline			(	0000	000	0			0x00
0xB7	STATUS	R/W	Device status one	0	0	0	0	0	0	0	0	0x00
0xB8	STATUS2	R/W	Device status two	0	0	0	0	0	0	0	0	0x00
0xB9	STATUS3	R/W	Device status three	0 0 0 0 0 0 0 0				0x00				
0xBA	STATUS4	R/W	Device status four	0	0	0	0	0	0	0	0	0x00
0xBB	STATUS5	R/W	Device status five		00	00		0	0	0	0	0x00
0xBD	STATUS7	R/W	Device status seven	0	0	0	0	0	0	0	0	0x00
0xBE	STATUS8	R/W	Device status eight	0	0	0	0	0	0	0	0	0x00
0xBF	STATUS9	R	Device status nine		00	00		0		000		0x00
0xC0	ASTATUS	R	ALS status			00	0000	00			0	0x00
0xC1						(	0000	000	0			0x00
0xC2	ADATA0	R	ALS channel zero data			(	0000	000	0			0x00
0xC3			0000000							0x00		
0xC4			0000000						0x00			
0xC5	ADATA1	R	ALS channel one data 00000000						0x00			
0xC6			00000000						0x00			
0xC7			00000000						0x00			
0xC8	ADATA2	R	ALS channel two data 00000000 00000000						0x00			
0xC9						l	0000	000	0			0x00



Addr	Name	Туре	Description 7 6 5 4 3 2 1 0					0	Reset			
0xCA			0000000						0x00			
0xCB	ADATA3	R	ALS channel three data			(	0000	000	0			0x00
0xCC						,	0000	0000	0			0x00
0xCD						(	0000	000	0			0x00
0xCE	ADATA4	R	ALS channel four data			(	0000	000	0			0x00
0xCF						,	0000	0000	0			0x00
0xD0						(	0000	000	0			0x00
0xD1	ADATA5	R	ALS channel five data			(	0000	000	0			0x00
0xD2						,	0000	0000	0			0x00
0xD3						(	າດດດ	000	0			0x00
0xD4	ADATA6	R	ALS channel six data					0x00				
0xD5			0000000				0x00					
0xD6			- 00000000						0x00			
0xD7	ADATA7	R	ALS channel seven data 00000000						0x00			
0xD8			0000000						0x00			
0xD9	PSTATUS	R	Proximity status	0	0			000	000			0x00
0xDA		R				. (	0000	0000	0			0x00
0xDB	PDATA0	К	Proximity channel zero data			(	0000	000	0		0x00	
0xDC		D				(	0000	0000	0			0x00
0xDD	PDATA1	R	Proximity channel one data			(	0000	000	0			0x00
0xDE						(	0000	0000	0			0x00
0xDF	PDATAR	R	Proximity channel ratio data 0000000			0000	0			0x00		
0xF2	GPIO	R/W	GPIO configuration 00 0 0				0	0	0	1	0	0x02
0xF4	AGC_GAIN_MAX	R/W	Maximum AGC gain 000				0			110		0x06
0xF5	INTENAB	R/W	Enable interrupts       0       0       0       0       0       0       0       0					0	0x00			
0xF6	CONTROL	R/W	Control 00000 0 0 0				0x00					
0xF7		<b>.</b>	Brovimity offset one 00000000					0x00				
0xF8	POFFSET1	R/W	Proximity offset one 00000000				0x00					
0xF9	FIFO_MAP	R/W	FIFO buffer map configuration $0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0$				0x00					

# am

Addr	Name	Туре	Description 7 6 5		4	3	2	1	0	Reset		
0xFA	FIFO_MAP2	R/W	FIFO buffer map configuration two					0x00				
0xFB	FIFO_STATUS	R	FIFO buffer status	0			00	0000	00			0x00
0xFC												0x00
0xFD	FDATA	R	FIFO buffer data					000	-			0x00
0xFE		Ň						000	-			0x00
0xFF												0x00

## **Detailed Register Descriptions**

## **ALS Interrupt Thresholds**

ALS level detection uses data generated by the ADC Channel X. The channel can be selected via ALS\_TH\_CHANNEL (see CFG12). The ALS Interrupt Threshold registers provide 24-bit values to be used as the high and low thresholds for comparison to the 24-bit ADATAX values. If AIEN is enabled and ADATAX is not between AILT and AIHT for the number of consecutive samples specified in APERS an interrupt is asserted on the interrupt pin. These registers are read/write.

**ALS Interrupt Thresholds** 

Bits	Addr	Field	Reset	Туре	Description
7:0	0x2E		0x00	R/W	
15:8	0x2F	AILT	0x00	R/W	ALS Interrupt Low Threshold
23:16	0x30		0x00	R/W	
7:0	0x31		0x00	R/W	
15:8	0x32	AIHT	0x00	R/W	ALS Interrupt High Threshold
23:16	0x33		0x00	R/W	

#### Note(s):

Figure 18:

1. Return to the Register Map (0x2E, 0x2F, 0x30, 0x31, 0x32, 0x33)

## Proximity Interrupt Thresholds

The Proximity Interrupt Threshold Registers set the high and low trigger points for the comparison function which generates an interrupt. Interrupt generation is subject to the value set in persistence filter (PPERS). These registers are read/write.

Bits	Addr	Field	Reset	Туре	Description
7:0	0x34	PILTO	0x00	R/W	Proximity Interrupt Low Threshold Zero
15:8	0x35	TIETO	0x00	R/W	
7:0	0x36	РІНТО	0x00	R/W	Proximity Interrupt High Threshold Zero
15:8	0x37		0x00	R/W	Troximity interrupt high threshold Zero
7:0	0x38	PILT1	0x00	R/W	Proximity Interrupt Low Threshold One
15:8	0x39	11211	0x00	R/W	Troximity interrupt Low Threshold One
7:0	0x3A	PIHT1	0x00	R/W	Proximity Interrupt High Threshold One
15:8	0x3B		0x00	R/W	Troximity interrupt high micshold one
7:0	0x3C	PILTR	0x00	R/W	Proximity Interrupt Low Threshold Ratio
15:8	0x3D		0x00	R/W	Troximity interrupt Low Theshold Natio
7:0	0x3E	PIHTR	0x00	R/W	Proximity Interrupt High Threshold Ratio
15:8	0x3F		0x00	R/W	

## Figure 19: Proximity Interrupt Thresholds

### Note(s):

1. Return to the Register Map (0x34, 0x35, 0x36, 0x37, 0x38, 0x39, 0x3A, 0x3B, 0x3C, 0x3D, 0x3E, 0x3F)

## Figure 20: FD\_CFG0

	Addr: 0x40			FD_CF	G0
Bit	Field	Reset	Туре	E	Bit Description
7:5	Reserved	000			
				Flicker Detection	n Number of Samples.
				VALUE	SAMPLES
12			DAM	0 (default)	128
4:3	FD_SAMPLES	00	R/W	1	256
				2	512
				3	1024 <sup>(2)</sup>
2	Reserved	0			
				Flicker Detection	n Time.
				VALUE	TIME
				0	50ms
1:0	FD_TIME	01	R/W	1 (default)	100ms
				2	200ms
				3	User defined by FD_SAMPLE_ TIME and FD_SAMPLES

## Note(s):

1. Return to the Register Map (0x40)

2. If FD\_MODE = 1 then number of samples changes from 1024 to unlimited.

Figure 21: FD\_CFG1

	Addr: 0x41			FD_CFG1
Bit	Field	Reset	Туре	Bit Description
7:5	Reserved	000		
4:0	FD_BIN0	00000	R/W	Flicker Detection Bin Zero. Coefficient to use for Bin 0.

## Note(s):

1. Return to the Register Map (0x41)

dm



Figure 22: FD\_CFG2

	Addr: 0x42			FD_CFG2
Bit	Field	Reset	Туре	Bit Description
7:5	Reserved	000		
4:0	FD_BIN1	00000	R/W	Flicker Detection Bin One. Coefficient to use for Bin 1.

### Note(s):

1. Return to the Register Map (0x42)

Figure 23: FD\_CFG3

	Addr: 0x43			FD_CFG3
Bit	Field	Reset	Туре	Bit Description
7:5	Reserved	000		
4:0	FD_BIN2	00000	R/W	Flicker Detection Bin Two. Coefficient to use for Bin 2.

## Note(s):

1. Return to the Register Map (0x43)

Figure 24: FD\_CFG4

	Addr: 0x44			FD_CFG4
Bit	Field	Reset	Туре	Bit Description
7:5	Reserved	000		
4:0	FD_BIN3	00000	R/W	Flicker Detection Bin Three. Coefficient to use for Bin 3.

### Note(s):

1. Return to the Register Map (0x44)

## Figure 25: FD\_CFG5

Addr: 0x45		FD_CFG5		
Bit	Field	Reset	Туре	Bit Description
7:0	FD_CHANNEL_DISABLE	0xFE	R/W	Flicker Detection Channel Disable. Selects which channels to be used for flicker detection.

### Note(s):

1. Return to the Register Map (0x45)

Figure 26: FD\_CFG7

Addr: 0x47		FD_CFG7		
Bit	Field	Reset	Reset Type Bit Description	
7:2	Reserved	000000		
1:0	FD_SAMPLE_TIME_H	01	R/W	<b>Flicker Detection Sample Time High.</b> These bits are the high byte of the 10 bits used for setting the flicker detection integration time.

### Note(s):

1. Return to the Register Map (0x47)

Figure 27: FD\_CFG8

Addr: 0x48		FD_CFG8			
Bit	Field	Reset Type Bit Description		Bit Description	
7:0	FD_SAMPLE_TIME_L	0x67	R/W	<b>Flicker Detection Sample Time Low.</b> This register is the low byte of the 10 bits used for setting the flicker detection integration time.	

### Note(s):

1. Return to the Register Map (0x48)



Figure 28: SYNC\_DELAY

B	Bits	Addr	Field	Reset	Туре	Description
	7:0	0x4F	SYNC DELAY	0x00	R/W	Synchronized Delay
1	4:8	0x50 [6:0]	JINC_DELAI	0000000	R/W	Synchronized Delay

### Note(s):

1. Return to the Register Map (0x4F, 0x50)

Figure 29: VSYNC\_CFG0

	Addr: 0x53	VSYNC_C			C_CFG0	
Bit	Field	Reset	Туре	Bit Description		
7:4	Reserved	0001				
3	VSYNC_FREQ_LL_IGNORE	0	R/W	VSYNC Frequ	ency Low Limit Ignore.	
2	Reserved	0				
				Oscillator Calibration Mode.		
				VALUE	MODE	
				0 (default)	No oscillator calibration	
1:0	:0 OSC_CAL_MODE 00 R/W	R/W	1	Single oscillator calibration after PON is set to 1.		
				2	Oscillator calibration is performed whenever possible	
				3	Reserved	

## Note(s):

1. Return to the Register Map (0x53)

### Figure 30: VSYNC\_CFG1

	Addr: 0x54	VSYNC_CFG1		
Bit	Field	Reset	Туре	Bit Description
7:6	Reserved	00		
5:0	VSYNC_FREQ	010000	R/W	Vertical SYNC Frequency. Frequency = 28Hz + (2Hz * VSYNC_FREQ)

### Note(s):

1. Return to the Register Map (0x54)

Figure 31: VSYNC\_CFG2

Addr: 0x56		VSYNC_CFG2		
Bit	Field	Reset	Reset Type Bit Description	
7:0	VSYNC_CFG2	0x00	R/W	<b>Vertical Sync Configuration Two.</b> Start time delay for first set of proximity pulses for SYNC measurement.

### Note(s):

1. Return to the Register Map (0x56)

Figure 32: VSYNC\_CFG3

Addr: 0x57		VSYNC_CFG3		
Bit	Field	Reset	Туре	Bit Description
7:0	VSYNC_CFG3	0x00	R/W	<b>Vertical Sync Configuration Three.</b> Start time delay for second set of proximity pulses for SYNC measurement.

#### Note(s):

1. Return to the Register Map (0x57)

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Figure 33: CALIB

	Addr: 0x69	CALIB			
Bit	Field	Reset Type Bit Description		Bit Description	
7:1	Reserved	0000000			
0	START_OFFSET_CALIB	0	PUSH	<b>Start Offset Calibration.</b> Starts the proximity offset register calibration routine. Results are stored in the Proximity Offset Registers (0xC7 – 0xC8). The CALIB_FINISHED flag is asserted when calibration is complete and an interrupt (CINT) is asserted if CIEN is set. Calibration can be stopped immediately by writing a 0 to this field.	

#### Note(s):

1. Return to the Register Map (0x69)

## Figure 34: CALIBCFG0

	Addr: 0x6A	CALIBCFG0				
Bit	Field	Reset	Туре	be Bit Description		
7	DCAVG_AUTO_BSLN	0	R/W	<b>DC Averaging Automatic Baseline.</b> Load the DC average calculated during offset calibration into the PBSLN registers at the end of calibration. Note that if the offset is adjusted (by zero detection) during the DC averaging, the average may be incorrect.		
6	DCAVG_AUTO_OFFSET_ ADJUST	0	R/W	<b>DC Averaging Auto Offset Adjust.</b> If set, then during DC averaging, whenever an ADC measurement is zero, the appropriate offset register will be decreased and the OFFSET_ ADJUSTED flag is set. Note also that DC averaging is not automatically restarted when this happens, so the calculated baseline might be wrong. Software could restart averaging in this case.		
5:4	Reserved	00				
3	BINSRCH_SKIP	0	R/W	<b>Binary Search Skip.</b> When asserted the calibration routine will skip the binary search step. It is useful if zeros are detected during the DC averaging process to manually reset the baseline and reduce the likelihood of zero counts.		
				<b>DC Averaging Iterations.</b> Sets the number of proximity results during calibration that are averaged after the binary search is complete During this period, whenever a result is zero, appropriate offset register is automatically decremented.		
				VALUE	ITERATIONS	
2:0	DCAVG_ITERATIONS	000	R/W	0	Skip	
				1	2	
				2	4	
					2 <sup>DCAVG_ITERATIONS</sup>	
				6	64	
				7	128	

### Note(s):

1. Return to the Register Map (0x6A)



Figure 35: CALIBCFG1

Addr: 0x6B			CALIBCFG1			
Bit	Field	Reset	Туре	Bit Description		
7	Reserved	0				
6	PROX_AUTO_OFFSET_ ADJUST	0	R/W	<b>Proximity Auto Offset Adjust.</b> If set, then during proximity/gesture mode, whenever an ADC measurement is zero, the appropriate offset register will be decreased. If this happens, OFFSET_ADJUSTED will be set to 1 and CINT will occur if enabled.		
5	PROX_SUBT_BSLN1	0	R/W	Proximity Subtract Basel	line One.	
4	PROX_SUBT_BSLN0	0	R/W	Proximity Subtract Basel	line Zero.	
3	PXAVG_AUTO_BSLN	1	R/W	<b>Proximity Average Auto Baseline Adjust.</b> If asserted, PBSLN is automatically updated with the value of PXAVG whenever PXAVG is less than previous PBSLN. If this happens, BASELINE_ ADJUSTED will be set to 1 and CINT will occur if enabled.		
				Proximity Average Iter of proximity results that normal proximity operat proximity average is stor the PXAVG registers afte complete.	tion. The resulting red as a 14-bit value in	
				VALUE	ITERATIONS	
2:0	PXAVG_ITERATIONS	100	R/W	0	Skip	
				1	2	
				2	4	
					2 <sup>DCAVG_ITERATIONS</sup>	
				6	64	
				7	128	

Note(s):

1. Return to the Register Map (0x6B)

## Figure 36: CALIBCFG2

Addr: 0x6C		CALIBCFG2				
Bit	Field	Reset	Туре	Bit Description		
				<b>Binary Search Target.</b> Sets the target value for proximity used during calibration. The target value is 2 <sup>(BINSRCH_TARGET + 2)</sup> – 1 counts.		
			VALUE	COUNTS		
			R/W	0	3	
7:5	BINSRCH_TARGET	000		1	7	
				2	15	
					2 <sup>(BINSRCH_TARGET + 2)</sup> -1	
				6	255	
				7	511	
4:0	Reserved	00000				

### Note(s):

1. Return to the Register Map (0x6C)

Figure 37: CALIBSTAT

Addr: 0x6D		CALIBSTAT			
Bit	Field	Reset	Туре	Bit Description	
7:3	Reserved	00000			
2	BASELINE_ADJUSTED	0	R/W	<b>Baseline Adjusted Automatically.</b> Indicates that PBSLN was reduced because PXAVG was smaller than PBSLN. Only occurs if PXAVG_AUTO_BSLN is set. Clear bit by writing 1 to it.	
1	OFFSET_ADJUSTED	0	R/W	<b>Offset Adjusted Automatically.</b> Indicates that proximity offset has been adjusted automatically. Only occurs if PROX_AUTO_OFFSET_ADJUST is set Clear bit by writing 1 to it.	
0	CALIB_FINISHED	0	R/W	<b>Calibration Finished.</b> Indicates that calibration is complete. Clear bit by writing 1 to it.	

### Note(s):

1. Return to the Register Map (0x6D)

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## Power, Enable, and Operation

The enable register has fields that power on the device and enable the functions. To operate the device, first set all configuration fields for all functions, then set PON = 1, and finally enable functions. Changing configuration register values while functions are operating may result in invalid results.

Addr: 0x80		ENABLE			
Bit	Field	Reset Type Bit Description		Bit Description	
7	Reserved	0			
6	FDEN	0	R/W	<b>Flicker Detection Enable.</b> Writing a 1 activates flicker detection. Writing a 0 disables flicker detection.	
5	Reserved	0			
4	AEN	0	R/W	<b>ALS Enable.</b> Writing a 1 enables ALS/Color. Writing a 0 disables ALS/Color.	
3	PEN	0	R/W	<b>Proximity Enable.</b> Writing a 1 enables proximity. Writing a 0 disables proximity.	
2:1	Reserved	00			
0	PON	0	R/W	<b>Power ON.</b> When asserted, the internal oscillator is activated, allowing timers and ADC channels to operate. Writing a 0 disables the oscillator and clears PEN and AEN. Only set this bit after all other registers have been initialized by the host.	

### Figure 38: ENABLE

#### Note(s):

1. Return to the Register Map (0x80)

Addr: 0x81		MEAS_MODE0			
Bit	Field	Reset	Туре	Bit Description	
7	Reserved	0			
6	CL_APF_VSYNC	0	R/W	Classical ALS Proximity Flicker Detection with next VSYNC.	
5:4	Reserved	00			
3:2	PROX_DIODE_ENABLE	00	R/W	<b>Proximity Diode Enable.</b> Write '11' to these two bits to enable the proximity diodes for measurement.	
1	ALS DIODE SELECTION	0	R/W	<b>ALS Diode Selection.</b> Select which chain mode to use for ALS measurements. Writing a 0 will select ALS Set A and writing a 1 will select ALS Set B.	
0	ALS_DIODE_ENABLE	0	R/W	<b>Enable ALS Diodes.</b> Write 1 to enable the ALS diodes for measurement.	

#### Note(s):

1. Return to the Register Map (0x81)

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Figure 40: MEAS\_MODE1

Addr: 0x82		MEAS_MODE1				
Bit	Field	Reset	Туре	Bit Description		
7	Reserved	0				
6	FD_MODE	0	R/W	<b>Flicker Detection Mode.</b> Writing a 0 will set the FD to on-chip mode and writing a 1 will set the FD to data sampling mode.		
5:3	Reserved	000	R/W			
	FIFO_MODE	0	R/W	FIFO Mode.		
				VALUE	MODE	
				0	Off	
2:0				1	32-bit	
				2	16-bit ALS	
				3	16-bit FD	
				4	8-bit FD	
				5 - 7	Reserved	

#### Note(s):

1. Return to the Register Map (0x82)

# Figure 41: TRIGGER\_MODE

Addr: 0x83		TRIGGER_MODE			
Bit	Field	Reset	Туре	Bit Des	scription
7	VSYNC_START_ALIGN	0	R/W	VSYNC Start Alignmen for ALS/Proximity/Flicke	<b>it.</b> Enables aligned start er with VSYNC.
				<b>Proximity Trigger Timi</b> trigger timing step.	<b>ng.</b> Selects Proximity
				VALUE	TIMING
			-	0	Off
				1	Normal (2.78ms)
6:4	PROX_TRIGGER_TIMING	000	R/W	2	Long (50ms)
				3	Fast (86.61µs)
				4	Fast/Long (1.56ms)
				5	VSYNC
				6, 7	Reserved
3	Reserved	0		Modulator Trigger Tim trigger timing step.	ing. Selects Modulator
				VALUE	TIMING
				0	Off
				1	Normal (2.78ms)
2:0	MOD_TRIGGER_TIMING	0	R/W	2	Long (50ms)
2.0			10/ 99	3	Fast (86.61µs)
			4	Fast/Long (1.56ms)	
				5	VSYNC
				6, 7	Reserved

## Note(s):

1. Return to the Register Map (0x83)

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Figure 42: ATIME

Addr: 0x84		ATIME				
Bit	Field	Reset	Туре	Bit Description		
			ALS Integration Time ALS/color integration s			
			VALUE	INTEGRATION TIME		
7:0	ATIME	0x00	R/W	0	ASTEP	
				n	ASTEP $\times$ ( <i>n</i> +1)	
				255	256  imes ASTEP	

# Note(s):

1. Return to the Register Map (0x84)

Figure 43: ASTEP

Bits	Addr	Field	Reset	Туре	Desc	ription
7:0	0x85		0xFF	R/W	ALS Integration Time 5 integration time per ste 2.7127µs. The default va read/write.	ep in increments of
			ASTEP 0x03 R/W		VALUE	STEP SIZE
		ASTEP			0	2.71µs
15:8	0x86			D/\\/	n	2.7127µs × ( <i>n</i> +1)
13.0	0,80	0,00		10 00	1023	2.78ms
			18431	50ms		
					65535	178ms

#### Note(s):

1. Return to the Register Map (0x85, 0x86)

## Figure 44: PTIME



Addr: 0x87		РТІМЕ			
Bit	Field	Reset	Туре	Bit Description	
7:0	PTIME	0x00	R/W	<b>Proximity Sample Time.</b> Sets the sample rate of proximity.	

# Note(s):

1. Return to the Register Map (0x87)

Figure 45: WTIME

	Addr: 0x88	WTIME		
Bit	Field	Reset	Туре	Bit Description
7:0	WTIME	0	R/W	<b>Wait Time.</b> Sets the sample rate of the ALS/color function.

#### Note(s):

1. Return to the Register Map (0x88)



Figure 46: MOD\_GAIN\_0\_1

Addr: 0x89		MOD_GAIN_0_1						
Bit	Field	Reset	Туре	Bit Description				
				Modulator One Gain.				
				VALUE	GAIN			
				0	2x			
				1	4x			
				2	8x			
				3	16x			
							4	32x
7:4	MOD_GAIN1	0000	R/W	5	64x			
				6	128x			
				7	256x			
				8	512x			
				9	1024x			
			10	2048x				
				11	4096x			
				12 - 15	Reserved			

# amu

Addr: 0x89		MOD_GAIN_0_1				
Bit	Field	Reset	Туре	Bit Description		
				Modulator Zero Gain.		
				VALUE	GAIN	
				0	2x	
				1	4x	
				2	8x	
				3	16x	
				4	32x	
3:0	MOD_GAIN0	0000	R/W	5	64x	
				6	128x	
				7	256x	
				8	512x	
				9	1024x	
				10	2048x	
				11	4096x	
				12 - 15	Reserved	

# Note(s):

1. Return to the Register Map (0x89)



Figure 47: MOD\_GAIN\_2\_3

Addr: 0x8A			MOD_GAIN_2_3				
Bit	Field	Reset	Туре	Bit Description			
				Modulator Three Gain.			
				VALUE	GAIN		
				0	2x		
				1	4x		
				2	8x		
				3	16x		
				4	32x		
7:4	MOD_GAIN3	0000	R/W	5	64x		
				6	128x		
				7	256x		
				8	512x		
				9	1024x		
			10	2048x			
				11	4096x		
				12 - 15	Reserved		

# amu

Addr: 0x8A		MOD_GAIN_2_3				
Bit	Field	Reset	Туре	Bit Description		
				Modulator Two Gain.		
				VALUE	GAIN	
				0	2x	
				1	4x	
				2	8x	
				3	16x	
				4	32x	
3:0	MOD_GAIN2	0000	R/W	5	64x	
				6	128x	
				7	256x	
				8	512x	
				9	1024x	
				10	2048x	
				11	4096x	
				12 - 15	Reserved	

# Note(s):

1. Return to the Register Map (0x8A)



Figure 48: MOD\_GAIN\_4\_5

Addr: 0x8B		MOD_GAIN_4_5						
Bit	Field	Reset	Туре	Bit Description				
				Modulator Five Gain.				
				VALUE	GAIN			
				0	2x			
				1	4x			
				2	8x			
				3	16x			
							4	32x
7:4	MOD_GAIN5	0000	R/W	5	64x			
				6	128x			
				7	256x			
				8	512x			
				9	1024x			
				10	2048x			
				11	4096x			
				12 - 15	Reserved			

# amu

Addr: 0x8B		MOD_GAIN_4_5				
Bit	Field	Reset	Туре	Bit Description		
				Modulator Four Gain.		
				VALUE	GAIN	
				0	2x	
				1	4x	
				2	8x	
				3	16x	
				4	32x	
3:0	MOD_GAIN4	0000	R/W	5	64x	
				6	128x	
				7	256x	
				8	512x	
				9	1024x	
				10	2048x	
				11	4096x	
				12 - 15	Reserved	

# Note(s):

1. Return to the Register Map (0x8B)



Figure 49: MOD\_GAIN\_6\_7

Addr: 0x8C			MOD_GAIN_6_7					
Bit	Field	Reset	Туре	Bit Description				
				Modulator Seven Gain.				
				VALUE	GAIN			
				0	2x			
				1	4x			
				2	8x			
				3	16x			
							4	32x
7:4	MOD_GAIN7	0000	R/W	5	64x			
				6	128x			
				7	256x			
				8	512x			
			9	1024x				
				10	2048x			
				11	4096x			
				12 - 15	Reserved			

# amu

Addr: 0x8C		MOD_GAIN_6_7				
Bit	Field	Reset	Туре	Bit Description		
				Modulator Six Gain.		
				VALUE	GAIN	
				0	2x	
				1	4x	
				2	8x	
				3	16x	
				4	32x	
3:0	MOD_GAIN6	0000	R/W	5	64x	
				6	128x	
				7	256x	
				8	512x	
				9	1024x	
				10	2048x	
				11	4096x	
				12 - 15	Reserved	

# Note(s):

1. Return to the Register Map (0x8C)



Figure 50: AGC\_ENABLE

	Addr: 0x8D			AGC_ENABLE
Bit	Field	Reset	Туре	Bit Description
7	AGC_ENABLE_MOD_7	0	R/W	<b>AGC Enable Modulator Seven.</b> If asserted, then device will use automatic gain control for the modulator seven to maximize ALS signal while avoiding saturation.
6	AGC_ENABLE_MOD_6	0	R/W	<b>AGC Enable Modulator Six.</b> If asserted, then device will use automatic gain control for the modulator six to maximize ALS signal while avoiding saturation.
5	AGC_ENABLE_MOD_5	0	R/W	<b>AGC Enable Modulator Five.</b> If asserted, then device will use automatic gain control for the modulator five to maximize ALS signal while avoiding saturation.
4	AGC_ENABLE_MOD_4	0	R/W	<b>AGC Enable Modulator Four.</b> If asserted, then device will use automatic gain control for the modulator four to maximize ALS signal while avoiding saturation.
3	AGC_ENABLE_MOD_3	0	R/W	<b>AGC Enable Modulator Three.</b> If asserted, then device will use automatic gain control for the modulator three to maximize ALS signal while avoiding saturation.
2	AGC_ENABLE_MOD_2	0	R/W	<b>AGC Enable Modulator Two.</b> If asserted, then device will use automatic gain control for the modulator two to maximize ALS signal while avoiding saturation.
1	AGC_ENABLE_MOD_1	0	R/W	<b>AGC Enable Modulator One.</b> If asserted, then device will use automatic gain control for the modulator one to maximize ALS signal while avoiding saturation.
0	AGC_ENABLE_MOD_0	0	R/W	<b>AGC Enable Modulator Zero.</b> If asserted, then device will use automatic gain control for the modulator zero to maximize ALS signal while avoiding saturation.

# Note(s):

1. Return to the Register Map (0x8D)



# Identification

The identification registers provide auxiliary identification for special cases, wafer revision data, and device identification. All identification registers are read only.

Figure 51: Identification Registers

Bits	Addr	Field	Reset	Туре	Description
7:0	0x90	AUXID	0x03	R	Auxiliary Identification.
7:0	0x91	REVID	0x13	R	Revision Identification.
7:0	0x92	ID	0x40	R	Device Identification.

#### Note(s):

1. Return to the Register Map (0x90, 0x91, 0x92)

Figure 52: CFG0

Addr: 0x93		CFG0			
Bit	Field	Reset	Туре	Bit Des	cription
7	Reserved	0			
6	LOWPOWER_IDLE	0	R/W	<b>Low Power Idle.</b> When asserted, the device wil automatically run in a low power mode whenever all functions are in wait states or disabled.	
5:3	Reserved	100			
				RAM Bank Selection. Sp access in registers 0x00 t	
				VALUE	BANK
2:0	RAM_BANK	000	R/W	0	0
				1	4
				2, 4, 5, 6, 7	Remote Control
				3	On-Chip Flicker

#### Note(s):

1. Return to the Register Map (0x93)



Figure 53: CFG3

Addr: 0x96		CFG3			
Bit	Field	Reset	Туре	Bit Description	
7:6	Reserved	00			
5	HXTALK_MODE1	0	R/W	<b>High Crosstalk Mode.</b> If asserted, the proximity engine uses a 10-bit output mode for no aperture proximity operation intended for extremely high optical crosstalk systems. HXTALK_MODE1 and HXTALK_MODE2 must both be asserted for this function to work.	
4	SAI	0	R/W	<b>Sleep After Interrupt.</b> If asserted, the oscillator is turned off whenever interrupt is active (low). SAI_ ACTIVE is set in this event. To activate the oscillator again, service and clear all interrupts plus clear the SAI_ACTIVE bit.	
3:0	Reserved	1111			

#### Note(s):

1. Return to the Register Map (0x96)

# Figure 54: CFG4

Addr: 0x97		CFG4				
Bit	Field	Reset	Туре	Bit Description		
				Interrupt Pin Map. Sel on the INT pin.	lects the signal to output	
				VALUE	INTERRUPT PIN	
				0	Normal	
				1	Reserved	
7:4	INT_PINMAP	0000	R/W	2	AINT Direct	
				3	PINT Direct	
				4, 5	Inverted	
				6	VCSEL pulse	
				7 - 15	Reserved	
				<b>GPIO Pin Map.</b> Selects the GPIO pin.	the signal to output on	
			R/W	VALUE	GPIO PIN	
				0	Normal	
				1	Reserved	
3:0	GPIO_PINMAP	0000		2	AINT Direct	
				3	PINT Direct	
				4, 5	Inverted	
				6	VCSEL pulse	
				7 - 15	Reserved	

#### Note(s):

1. Return to the Register Map (0x97)

Persistence filters limit the rate of interrupts generated for proximity and ALS/color data.

dm



Figure 55: PERS

1	Addr: 0x9A	PERS			
Bit	Field	Reset	Туре		Bit Description
				number of c remain outsi before an int	<b>Atterrupt Persistence.</b> Defines a filter for the onsecutive occurrences that PDATA must ide the threshold range between PILT and PIHT terrupt is generated. Any sample that is inside d range resets the counter to 0.
				VALUE	CONSECUTIVE PDATA OUT OF RANGE TO INTERRUPT
7:4	PPERS	0001	R/W	0	Every proximity cycle generates an interrupt
				1	1
				2	2
					PPERS
				15	15
				of consecution outside the tan interrupt persistence f	<b>pt Persistence.</b> Defines a filter for the number ve occurrences that ALS/color data must remain threshold range between AILT and AIHT before is generated. The ALS data channel used for the filter is set by ALS_TH_CHANNEL. Any sample the threshold range resets the counter to 0.
				VALUE	CONSECUTIVE ADATA OUT OF RANGE TO INTERRUPT
				0	Every ALS cycle generates an interrupt
3:0	APERS	0001	R/W	1	1
				2	2
				3	3
				4	5
				5	10
					5 × (APERS – 3)
				14	55
				15	60

## Note(s):

1. Return to the Register Map (0x9A)

# amu

# Figure 56: CFG8

Addr: 0x9B		CFG8				
Bit	Field	Reset Type Bit Description			cription	
			<b>FIFO Threshold.</b> Sets a t level that triggers the firs (FINT).			
			10 R/W	VALUE	FIFO_LVL	
7:6	FIFO_THR	10		0	1	
				1	8	
				2	16	
				3	32	
5:0	Reserved	000000				

# Note(s):

1. Return to the Register Map (0x9B)

Figure 57: CFG9

Addr: 0x9C		CGF9			
Bit	Field	Reset	Туре	Bit Description	
7	Reserved	0			
6	SIEN_FD	0	R/W	<b>System Interrupt Flicker Detection.</b> Enables system interrupt when flicker detection status change has occurred.	
5:0	Reserved	000000			

# Note(s):

1. Return to the Register Map (0x9C)



Figure 58: CFG10

Addr: 0x9D			CFG10				
Bit	Field	Reset	Туре	Bit Description			
				ALS AGC High Hysteres threshold at which AGAII AGC mode is enabled. Th automatically calculated percentage of full-scale. I equal to (ATIME + 1) $\times$ (A	N is reduced when ALS ie threshold is internally as a Note that full-scale is		
7:6	ALS_AGC_HIGH_HYST	11	R/W	VALUE	SIGNAL		
				0	50%		
				1	62.5%		
				2	75%		
				3	87.5%		
						ALS AGC Low Hysteresis threshold at which AGAIN AGC mode is enabled. The automatically calculated percentage of full-scale. I equal to (ATIME + 1) $\times$ (A	N is increased when ALS ie threshold is internally as a Note that full-scale is
5:4	ALS_AGC_LOW_HYST	11	R/W	VALUE	SIGNAL		
				0	12.5%		
				1	25%		
				2	37.5%		
				3	50%		
3:0	Reserved	0010					

## Note(s):

1. Return to the Register Map (0x9D)

Figure	59:
CFG11	

Addr: 0x9E		CFG11			
Bit	Field	Reset	Туре	Bit Description	
7	AINT_DIRECT	0	R/W	<b>ALS Interrupt Direct.</b> Enables the direct mode of ALS interrupt. The status of the ALS interrupt is directly output on the INT pin if this mode is enabled and the pin is configured to do so according to the INT_PINMAP setting.	
6	PINT_DIRECT	1	R/W	<b>Proximity Interrupt Direct.</b> If asserted, the proximity interrupt has a hysteresis loop built into the interrupt. After setting PEN = 1, the device interrupts once PDATA is below PILT or above PIHT. After this initial interrupt, the device will then interrupt based on the direction that the PDATA changes relative to each threshold. An interrupt is generated when PDATA increases from below to above PIHT to indicate a Detect condition, and an interrupt is generated when PDATA decreases from above to below PILT to indicate a Release condition. With built-in hysteresis, it is no longer necessary to change the thresholds between Detect or Release interrupts. This bit applies to PINT0 and PINT1 by using PDATA0 and PDATA1 respectively, as well as the respective thresholds.	
5:0	Reserved	000000			

#### Note(s):

1. Return to the Register Map (0x9E)

amu



Figure 60: CFG12

	Addr: 0x9F	CFG12					
Bit	Field	Reset	Туре		Bit Description		
7:3	Reserved	00000					
		ι	used for interru	<b>s Channel.</b> Sets t pts and persisten ce status and ALS	ce if enabled, to		
				VALUE	CHANNEL	DEFAULT	
				0	0	CLEAR	
				1	1	RED	
2:0	ALS_TH_CHANNEL	000	R/W	R/W	2	2	GREEN
				3	3	BLUE	
				4	4	LEAKAGE	
				5	5	WIDEBAND	
				6	6	IR1	
				7	7	IR2	

## Note(s):

1. Return to the Register Map (0x9F)



ALS autozero configuration is used to set how often the ALS engine offsets are reset to compensate for changes in device temperature.

# Figure 61: AZ\_CONFIG

	Addr: 0xA4			AZ	_CONFIG	
Bit	Field	Reset	Туре		Bit Description	
		Over R/W		<b>zero Frequency.</b> Sets the frequency at device performs autozero of the ALS nter.		
				VALUE	AUTOZERO FREQUENCY	
			0xFF R/W		0	Never
7:0	AZ_NTH_ITERATION				1	Every cycle
7.0		UXI I		Every 2 cycles		
					Every (AZ_NTH_ITERATION) cycles	
				253	Every 253 cycles	
				254	Every 254 cycles	
				255	Only once (before 1st cycle)	

#### Note(s):

1. Return to the Register Map (0xA4)



Figure 62: CFG20

	Addr: 0xA7		CFG20			
Bit	Field	Reset	Туре	Bit Description		
7:5	Reserved	000				
4	FLICKER_FIFO_MODE	0	R/W	Flicker FIFO Mode.		
3:0	Reserved	0000				

## Note(s):

1. Return to the Register Map (0xA7)

Figure 63: PCFG1

	Addr: 0xAA		PCFG1			
Bit	Field	Reset	Reset Type Bit Descrip		cription	
7	HXTALK_MODE2	0	R/W	High Crosstalk Mode. If engine uses a 10-bit outp proximity operation inter optical crosstalk systems HXTALK_MODE2 must be function to work.	out mode for no aperture nded for extremely high . HXTALK_MODE1 and	
6:4	Reserved	000				
3	PROX_FILTER_DOWNSAMPLE	0	R/W	<b>Proximity Filter Down Sample.</b> Sets how often proximity results are checked for interrupts and persistence when PROX_FILTER is enabled.		
				<b>Proximity Filter.</b> Selects proximity, <i>n</i> . The average length <i>n</i> , and the result is either every cycle (PROX = 0) or every <i>n</i> cycles (PR DOWNSAMPLE = 1).	e is a moving window of s updated and used _FILTER_DOWNSAMPLE	
			5.44	VALUE	FILTER LENGTH	
2:0	PROX_FILTER	000	R/W	0	1	
				1	2	
					PROX_FILTER + 1	
				6	7	
				7	8	

#### Note(s):

1. Return to the Register Map (0xAA)

## Figure 64: PCFG2

	Addr: 0xAB		PCFG2			
Bit	Field	Reset	Reset Type Bit Description		cription	
				Current Sink Release So used during release sett		
				VALUE	SCALER	
7:6	ISINK_RELEASE	00	R/W	0	0.5	
				1	1	
				2	1.5	
				3	2	
		00	R/W	Current Sink Detect Sca used during detect setting		
				VALUE	SCALER	
5:4	ISINK_DETECT			0	0.5	
				1	1	
				2	1.5	
				3	2	
				Current Sink Slave Two.		
			R/W	VALUE	CURRENT	
3:0	ILEDS2_SINK2 <sup>(2)</sup>	0000		0	0 mA	
					<i>n</i> mA	
				7	7 mA	

#### Note(s):

1. Return to the Register Map (0xAB)

2. The maximum value setting is limited to a maximum of 7.

# amu



Figure 65: PCFG3

	Addr: 0xAC	PCFG3				
Bit	Field	Reset	Туре	Bit Desc	cription	
				Current Sink Slave One.		
		0 R/W	VALUE	CURRENT		
7:4	ILEDS1_SINK1 <sup>(2)</sup>		0	0 mA		
					<i>n</i> mA	
				7	7 mA	
				Current Sink Master Zero.		
				VALUE	CURRENT	
3:0	ILEDM0_SINK0 <sup>(2)</sup>	0	R/W	0	1 mA	
					<i>n</i> +1 mA	
				7	8 mA	

# Note(s):

1. Return to the Register Map (0xAC)

2. The maximum value setting is limited to a maximum of 7.

## Figure 66: PCFG4

	Addr: 0xAD		PCFG4				
Bit	Field	Reset	Туре	Bit Description			
7:4	Reserved	0000					
				Proximity Gain One. Sets engine one.	the gain for proximity		
				VALUE	PROXIMITY GAIN		
3:2	PGAIN1	10	10 R/W	0	1x		
				1	2x		
				2	4x		
				3	8x		
				Proximity Gain Zero. Set engine zero.	s the gain for proximity		
				VALUE	PROXIMITY GAIN		
1:0	PGAIN0	10	R/W	0	1x		
				1	2x		
				2	4x		
				3	8x		

# Note(s):

1. Return to the Register Map (0xAD)

Figure 67: PCFG5

	Addr: 0xAE			PCFG5
Bit	Field	Reset	Туре	Bit Description
7:0	PPULSE	0x0F	R/W	<b>Proximity Pulse Count.</b> Specifies the maximum number of proximity pulses per sample. The number of pulses is equal to PPULSE + 1. The pulse count can be set between 1 and 256 pulses.

### Note(s):

1. Return to the Register Map (0xAE)

am



Figure 68: PCFG6

	Addr: 0xAF	PCFG6			
Bit	Field	Reset	Туре	Bit Description	
7	PDATA_EVAL_CH	0	R/W	<b>Proximity Evaluation Channel.</b> This bit selects which channel is used for the proximity baseline calculation. If set to 0 then PDATA0 is used, if set to 1 then PDATA1 is used.	
6:4	Reserved	000			
3	PDATA1_H_AND	0	R/W	<b>Proximity One High Threshold And.</b> If set to 1 then the high threshold of PDATA1 is seen as an AND for the proximity interrupt.	
2	PDATA1_L_AND	0	R/W	<b>Proximity One Low Threshold And.</b> If set to 1 then the low threshold of PDATA1 is seen as an AND for the proximity interrupt.	
1	PDATA0_H_AND	0	R/W	<b>Proximity Zero High Threshold And.</b> If set to 1 then the high threshold of PDATA0 is seen as an AND for the proximity interrupt.	
0	PDATA0_L_AND	0	R/W	<b>Proximity Zero Low Threshold And.</b> If set to 1 then the low threshold of PDATA0 is seen as an AND for the proximity interrupt.	

### Note(s):

1. Return to the Register Map (0xAF)

Figure 69: PCFG7

	Addr: 0xB0		PCFG7			
Bit	Field	Reset	Туре		Bit Description	
7:5	Reserved	000				
4	PROX_PRE_FILTER	0	R/W	<b>Proximity Pre-Filter.</b> When this bit is set, the 2 most recent proximity integrations will be combined and PDATA will be ~2x the value of single integration when this bit is not set.		
3	Reserved	0				
			<b>Proximity</b> pulse leng	<b>y Pulse Length.</b> Sets the proximity gth.		
				VALUE	PULSE LENGTH	
				0	4µs	
				1	8µs	
2:0	PPULSE_LEN	001	R/W	2	16µs	
				3	32µs	
				4	64µs	
				5	128µs	
				6	256µs	
				7	512µs	

# Note(s):

1. Return to the Register Map (0xB0)

Figure 70: POFFSET0

Bits	Addr	Field	Reset	Туре	Description
7:0	0xB1	POFFSET0	0x00	R/W	Proximity Offset Zero
15:8	0xB2	TOTTSETU	0x00	R/W	

# Note(s):

1. Return to the Register Map (0xB1, 0xB2)

am



Figure 71: PXAVG

Bits	Addr	Field	Reset	Туре	Description
7:0	0xB3	PXAVG	0x00	R/W	Proximity Average
15:8	0xB4		0x00	R/W	Troximity Average

# Note(s):

1. Return to the Register Map (0xB3, 0xB4)

Figure 72: PBSLN

Bits	Addr	Field	Reset	Туре	Description
7:0	0xB5	PBSLN	0x00	R/W	Proximity Baseline
15:8	0xB6	TUSEN	0x00	R/W	

#### Note(s):

1. Return to the Register Map (0xB5, 0xB6)



# **Status Registers**

The primary status register for TMD3719 indicates if there are saturation or interrupt events that need to be handled by the user. This register is self-clearing, meaning that writing a 1 to any bit in the register clears that status bit. In this way, the user should read the STATUS register, handle all indicated event(s), then write the register value back to STATUS to clear the handled events. Writing 0 to these bits will not clear those bits if they have a value of 1, which means that new events that occurred since the last read of the STATUS register will not be accidentally cleared.

Figure 73: STATUS

Ado	Addr: 0xB7		STATUS		
Bit	Field	Reset	Туре	Bit Description	
7	ASAT	0	R	<b>ALS Saturation.</b> If ASIEN is set, indicates ALS saturation. Check the STATUS3 register to differentiate between analog or digital saturation.	
6	FDSAT	0	R	Flicker Detection Saturation. If FDSIEN is set, indicates Flicker Detection saturation. Check the STATUS4 register to differentiate between analog or digital saturation.	
5	PSAT	0	R	<b>Proximity Saturation.</b> If PSIEN is set, indicates analog saturation during a previous proximity cycle. Check the STATUS2 register to differentiate between ambient or reflected light saturation.	
4	PINT	0	R	<b>Proximity Interrupt One.</b> If PIEN is set, indicates that a proximity detect or release event that met the programmed proximity thresholds and persistence occurred.	
3	AINT	0	R	<b>ALS Interrupt.</b> If AIEN is set, indicates that an ALS event that met the programmed ALS thresholds and persistence occurred.	
2	FINT	0	R	<b>FIFO Buffer Interrupt.</b> If FIEN is set, indicates that the FIFO_LVL fulfills the threshold condition. If cleared by writing 1, the interrupt will be asserted again as more data is collected. To fully clear this interrupt, all data must be read from the FIFO buffer.	
1	CINT	0	R	<b>Calibration Interrupt.</b> If CIEN is set, indicates that either calibration is finished or that one of certain events have occurred during normal operation. If each function is enabled, CINT will be asserted if too many zeros occur too often in a period of samples, if the proximity baseline has decreased, or if at least one offset register has been adjusted. Check the CALIBSTAT register to identify the triggering event(s).	
0	SINT	0	R	<b>System Interrupt.</b> If SIEN is set, indicates that one or more of several events has occurred or is complete. The events related to this interrupt are indicated in the STATUS5 register (0xBB): flicker detection register status has changed.	

#### Note(s):

1. Return to the Register Map (0xB7)



Additional status registers indicate details about saturation, interrupts, and device execution.

Figure 74: STATUS2

Addr: 0xB8				STATUS2
Bit	Field	Reset	Туре	Bit Description
7	PVALID	0	R	<b>Proximity Valid.</b> Indicates that the proximity state has completed a cycle since either an assertion of PEN or the last readout of PDATA.
6	AVALID	0	R	<b>ALS Valid.</b> Indicates that the ALS state has completed a cycle since either an assertion of AEN or the last readout of the ASTATUS register.
5	PSAT1_ADC	0	R	<b>Proximity One ADC Saturation.</b> Indicates that the maximum proximity ADC value has occurred for proximity channel one during proximity measurement.
4	PSAT1_ REFLECTIVE	0	R	<b>Proximity One Reflective Saturation.</b> Indicates that the intensity of reflected light has exceeded the maximum integration level for the proximity analog circuit for channel one during proximity measurement.
3	PSAT1_ AMBIENT	0	R	<b>Proximity One Ambient Saturation.</b> Indicates that the intensity of ambient light has exceeded the maximum integration level for the proximity analog circuit for channel one during proximity measurement.
2	PSAT0_ADC	0	R	<b>Proximity Zero ADC Saturation.</b> Indicates that the maximum proximity ADC value has occurred for proximity channel zero during proximity measurement.
1	PSAT0_ REFLECTIVE	0	R	<b>Proximity Zero Reflective Saturation.</b> Indicates that the intensity of reflected light has exceeded the maximum integration level for the proximity analog circuit for channel zero during proximity measurement.
0	PSATO_ AMBIENT	0	R	<b>Proximity Zero Ambient Saturation.</b> Indicates that the intensity of ambient light has exceeded the maximum integration level for the proximity analog circuit for channel zero during proximity measurement.

#### Note(s):

1. Return to the Register Map (0xB8)

Figure 75:
STATUS3

	Addr: 0xB9	STATUS3				
Bit	Field	Reset	Туре	Bit Description		
7	ASAT7_ANALOG	0	R	<b>ALS Channel Seven Analog Saturation.</b> Indicates that the intensity of ambient light has exceeded the maximum integration level for the ALS channel seven analog circuit.		
6	ASAT6_ANALOG	0	R	<b>ALS Channel Six Analog Saturation.</b> Indicates that the intensity of ambient light has exceeded the maximum integration level for the ALS channel six analog circuit.		
5	ASAT5_ANALOG	0	R	<b>ALS Channel Five Analog Saturation.</b> Indicates that the intensity of ambient light has exceeded the maximum integration level for the ALS channel five analog circuit.		
4	ASAT4_ANALOG	0	R	<b>ALS Channel Four Analog Saturation.</b> Indicates that the intensity of ambient light has exceeded the maximum integration level for the ALS channel four analog circuit.		
3	ASAT3_ANALOG	0	R	<b>ALS Channel Three Analog Saturation.</b> Indicates that the intensity of ambient light has exceeded the maximum integration level for the ALS channel three analog circuit.		
2	ASAT2_ANALOG	0	R	<b>ALS Channel Two Analog Saturation.</b> Indicates that the intensity of ambient light has exceeded the maximum integration level for the ALS channel two analog circuit.		
1	ASAT1_ANALOG	0	R	ALS Channel One Analog Saturation. Indicates that the intensity of ambient light has exceeded the maximum integration level for the ALS channel one analog circuit.		
0	ASAT0_ANALOG	0	R	<b>ALS Channel Zero Analog Saturation.</b> Indicates that the intensity of ambient light has exceeded the maximum integration level for the ALS channel zero analog circuit.		

## Note(s):

1. Return to the Register Map (0xB9)

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Figure 76: STATUS4

	Addr: 0xBA		STATUS4		
Bit	Field	Reset	Туре	Bit Description	
7	OSCCAL_SAT	0	R	Oscillator Calibration Saturation.	
6	Reserved	0			
5	OSCCAL_FINISHED	0	R	Oscillator Calibration Finished.	
4	FD_SAT_DETECTED	0	R	<b>Flicker Saturation Detected.</b> Indicates that saturation occurred during the last flicker detection measurement, and the result may not be valid. Write 1 to this bit to clear this field.	
3	FD_BUSY	0	R	Flicker Detection Busy. Indicates flicker detection is in progress.	
2	FD_TRIG_ERROR	0	R	<b>Flicker Detect Trigger Error.</b> Indicates that there is a timing error that prevents flicker detect from functioning correctly.	
1	PROX_TRIG_ERROR	0	R	<b>Proximity Trigger Error.</b> Indicates that there is a timing error that prevents proximity from functioning correctly. The number of pulses and/or pulse length are too long for the PTIME configured for the device.	
0	MOD_TRIG_ERROR	0	R	<b>Modulator Trigger Error.</b> Indicates that there is a timing error that prevents ALS from functioning correctly. The WTIME is too short for the ATIME configured for the device.	

### Note(s):

1. Return to the Register Map (0xBA)

# amu

Figure 77: STATUS5

	Addr: 0xBB	STATUS5			
Bit	Field	Reset	Туре	Bit Description	
7:4	Reserved	0000			
3	SINT_FD	0	R	<b>Flicker Detect Interrupt.</b> If SIEN_FD is set, indicates that the FD_STATUS register status has changed.	
2:1	Reserved	00			
0	SINT_SYNC_ERROR	0	R	<b>Synchronization Error Interrupt.</b> If SINT_SYNC_ERROR is set, indicates there was a synchronization error.	

## Note(s):

1. Return to the Register Map (0xBB)

Figure 78: STATUS7

	Addr: 0xBD		STATUS7		
Bit	Field	Reset	Туре	Bit Description	
7	AINT_AIHT	0	R	<b>ALS Interrupt High.</b> Indicates that an ALS interrupt occurred because the ALS data exceeded the high threshold.	
6	AINT_AILT	0	R	<b>ALS Interrupt Low.</b> Indicates that an ALS interrupt occurred because the ALS data is below the low threshold.	
5:4	Reserved	00			
3	PINT1_PIHT	0	R	<b>Proximity One Interrupt High.</b> Indicates that a proximity one interrupt occurred because the proximity one data exceeded the high threshold.	
2	PINT1_PILT	0	R	<b>Proximity One Interrupt Low.</b> Indicates that a proximity one interrupt occurred because the proximity one data is below the low threshold.	
1	PINTO_PIHT	0	R	<b>Proximity Zero Interrupt High.</b> Indicates that a proximity zero interrupt occurred because the proximity zero data exceeded the high threshold.	
0	PINTO_PILT	0	R	<b>Proximity Zero Interrupt Low.</b> Indicates that a proximity zero interrupt occurred because the proximity zero data is below the low threshold.	

# Note(s):

1. Return to the Register Map (0xBD)

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Figure 79: STATUS8

	Addr: 0xBE	STATUS8			
Bit	Field	Reset	Туре	Bit Description	
7:6	Reserved	00			
5	FVALID	0	R	<b>Flicker Data Valid.</b> Indicates that the flicker detection has completed a cycle since assertion of FDEN or since the last readout of the FSTATUS register.	
4	Reserved	0			
3	SYNC_LOST	0	R	<b>Synchronization Lost.</b> Indicates when synchronization of VSYNC is lost.	
2	Reserved	0			
1	SAI_ACTIVE	0	R	<b>Sleep After Interrupt Active.</b> Indicates that the device is in SLEEP due to an interrupt. To exit SLEEP mode, clear this bit.	
0	INIT_BUSY	0	R	<b>Initialization Busy.</b> Indicates that the device is initializing. This bit will remain 1 for about 300µs after power on. Do not interact with the device until initialization is complete.	

# Note(s):

1. Return to the Register Map (0xBE)

Figure 80: STATUS9

	Addr: 0xBF		STATUS9				
Bit	Field	Reset	Туре	Bit Description			
7:4	Reserved	0000					
3	SYNC_ERROR	0	R	Synchronization Error			
2:0	Reserved	000					

### Note(s):

1. Return to the Register Map (0xBF)



# Figure 81: ASTATUS

	Addr: 0xC0	ASTATUS				
Bit	Field	Reset	Туре	Bit Description		
7:1	Reserved	0000000				
0	ASAT_STATUS	0	R	<b>ALS Saturation Status.</b> Indicates if the latched ALS data is affected by analog or digital saturation.		

# Note(s):

1. Return to the Register Map (0xC0)



Bits	Addr	Field	Reset	Туре	Description
7:0	0xC1		0x00	R	
15:8	0xC2	ADATA0	0x00	R	ALS Channel Zero Data. CLEAR data
23:16	0xC3		0x00	R	
7:0	0xC4		0x00	R	
15:8	0xC5	ADATA1	0x00	R	ALS Channel One Data. RED data
23:16	0xC6		0x00	R	
7:0	0xC7		0x00	R	
15:8	0xC8	ADATA2	0x00	R	ALS Channel Two Data. GREEN data
23:16	0xC9		0x00	R	
7:0	0xCA		0x00	R	
15:8	0xCB	ADATA3	0x00	R	ALS Channel Three Data. BLUE data
23:16	0xCC		0x00	R	
7:0	0xCD		0x00	R	
15:8	0xCE	ADATA4	0x00	R	ALS Channel Four Data. LEAKAGE data
23:16	0xCF		0x00	R	
7:0	0xD0		0x00	R	
15:8	0xD1	ADATA5	0x00	R	ALS Channel Five Data. WIDEBAND data
23:16	0xD2		0x00	R	
7:0	0xD3		0x00	R	
15:8	0xD4	ADATA6	0x00	R	ALS Channel Six Data. IR1 data
23:16	0xD5		0x00	R	
7:0	0xD6		0x00	R	
15:8	0xD7	ADATA7	0x00	R	ALS Channel Seven Data. IR2 data
23:16	0xD8		0x00	R	]

### Note(s):

1. Return to the Register Map (0xC1, 0xC2, 0xC3, 0xC4, 0xC5, 0xC6, 0xC7, 0xC8, 0xC9, 0xCA, 0xCB, 0xCC, 0xCD, 0xCE, 0xCF, 0xD0, 0xD1, 0xD2, 0xD3, 0xD4, 0xD5, 0xD6, 0xD7, 0xD8).

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Figure 83: PSTATUS

	Addr: 0xD9	PSTATUS			
Bit	Field	Reset	Туре	Bit Description	
7	Reserved	0			
6	SMUX_PRX_MS_STAT	0	R	SMUX Proximity Mode Select Status.	
5:0	PSAT_STATUS	000000	R	<b>Proximity Saturation Status.</b> Indicates if the latched proximity data is affected by analog or digital saturation.	

#### Note(s):

1. Return to the Register Map (0xD9)

Figure 84: Proximity Data

Bits	Addr	Field	Reset	Туре	Description
7:0	0xDA	PDATA0	0x00	R	Proximity Data Zero
15:8	0xDB	1 DAIA	0x00	R	
7:0	0xDC	PDATA1	0x00	R	Proximity Data One
15:8	0xDD		0x00	R	
7:0	0xDE	PDATAR	0x00	R	Proximity Data Ratio
15:8	0xDF		0x00	R	

#### Note(s):

1. Return to the Register Map (0xDA, 0xDB, 0xDC, 0xDD, 0xDE, 0xDF)

Figure 85: GPIO

	Addr: 0xF2	GPIO			
Bit	Field	Reset	Туре	Bit Description	
7:6	Reserved	00			
5	INT_INVERT	0	R/W	<b>Interrupt Invert.</b> If asserted, the output on interrupt pin is inverted. This is useful for direct interrupt output if active = high.	
4	INT_IN_EN	0	R/W	<b>Interrupt Input Enable.</b> If asserted, the interrupt pin can be used as an input.	
3	GPIO_INVERT	0	R/W	<b>GPIO Invert.</b> If asserted, the output on GPIO is inverted. This is useful for direct interrupt output if active = high.	
2	GPIO_IN_EN	0	R/W	<b>GPIO Input Enable.</b> If asserted, the GPIO pin accepts a non-floating input.	
1	GPIO_OUT	1	R/W	<b>GPIO Output.</b> If asserted, the output state of the GPIO is active directly.	
0	GPIO_IN	0	R/W	<b>GPIO Input.</b> Indicates the status of the GPIO input if GPIO_IN_EN is asserted.	

#### Note(s):

1. Return to the Register Map (0xF2)

Figure 86: AGC\_GAIN\_MAX

	Addr: 0xF4	AGC_GAIN_MAX			
Bit	Field	Reset	Туре	Bit Description	
7:3	Reserved	00000			
2:0	AGC_MOD_GAIN_MAX	110	R/W	<b>AGC Modulator Gain Max.</b> Sets the maximum modulator gain for the AGC engine.	

### Note(s):

1. Return to the Register Map (0xF4)

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Figure 87: INTENAB

	Addr: 0xF5	INTENAB			
Bit	Field	Reset	Туре	Bit Description	
7	ASIEN	0	R/W	<b>ALS Saturation Interrupt Enable.</b> When asserted permits ALS saturation interrupts to be generated.	
6	FDSIEN	0	R/W	Flicker Detect Saturation Interrupt Enable. When asserted permits flicker detection saturation interrupts to be generated.	
5	PSIEN	0	R/W	<b>Proximity Saturation Interrupt Enable.</b> When asserted permits proximity saturation interrupts to be generated.	
4	PIEN	0	R/W	<b>Proximity Interrupt Enable.</b> When asserted permits proximity interrupts to be generated, subject to the proximity thresholds and persistence filter.	
3	AIEN	0	R/W	<b>ALS Interrupt Enable.</b> When asserted permits ALS interrupts to be generated, subject to the ALS thresholds and persistence filter. Bit is mirrored in the ENABLE register.	
2	FIEN	0	R/W	<b>FIFO Buffer Interrupt Enable.</b> When asserted permits interrupt to be generated when FIFO_LVL exceeds the FIFO threshold condition.	
1	CIEN	0	R/W	<b>Calibration Interrupt Enable.</b> When asserted permits calibration interrupts to be generated.	
0	SIEN	0	R/W	<b>System Interrupt Enable.</b> When asserted permits system interrupts to be generated. Indicates that flicker detection status has changed.	

#### Note(s):

1. Return to the Register Map (0xF5)

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### Figure 88: CONTROL

	Addr: 0xF6	CONTROL			
Bit	Field	Reset	Туре	Bit Description	
7:3	Reserved	00000			
2	ALS_MANUAL_AZ	0	R/W	<b>ALS Manual Autozero.</b> Starts a manual autozero of the ALS engines. Set AEN = 0 before starting a manual autozero for it to work.	
1	FIFO_CLR	0	R/W	<b>FIFO Buffer Clear.</b> Clears all FIFO data, FINT, FIFO_OV, and FIFO_LVL.	
0	CLEAR_SAI_ACTIVE	0	R/W	<b>Clear Sleep-After-Interrupt Active.</b> Clears SAI_ACTIVE, ends sleep, and restarts device operation.	

### Note(s):

1. Return to the Register Map (0xF6)

Figure 89: POFFSET1

Bits	Addr	Field	Reset	Туре	Description
7:0	0xF7	POFFSET1	0x00	R/W	Proximity Offset One
15:8	0xF8	TOTTSETT	0x00	R/W	Thousand y onset one

### Note(s):

1. Return to the Register Map (0xF7, 0xF8)



Figure 90: FIFO\_MAP

	Addr: 0xF9	FIFO_MAP			
Bit	Field	Reset	Туре	Bit Description	
7	FIFO_WRITE_ADATA7	0	R/W	<b>FIFO Write ALS Data Seven.</b> If asserted, ADATA7 is written to the FIFO Buffer.	
6	FIFO_WRITE_ADATA6	0	R/W	<b>FIFO Write ALS Data Six.</b> If asserted, ADATA6 is written to the FIFO Buffer.	
5	FIFO_WRITE_ADATA5	0	R/W	<b>FIFO Write ALS Data Five.</b> If asserted, ADATA5 is written to the FIFO Buffer.	
4	FIFO_WRITE_ADATA4	0	R/W	<b>FIFO Write ALS Data Four.</b> If asserted, ADATA4 is written to the FIFO Buffer.	
3	FIFO_WRITE_ADATA3	0	R/W	<b>FIFO Write ALS Data Three.</b> If asserted, ADATA3 is written to the FIFO Buffer.	
2	FIFO_WRITE_ADATA2	0	R/W	<b>FIFO Write ALS Data Two.</b> If asserted, ADATA2 is written to the FIFO Buffer.	
1	FIFO_WRITE_ADATA1	0	R/W	<b>FIFO Write ALS Data One.</b> If asserted, ADATA1 is written to the FIFO Buffer.	
0	FIFO_WRITE_ADATA0	0	R/W	<b>FIFO Write ALS Data Zero.</b> If asserted, ADATA0 is written to the FIFO Buffer.	

#### Note(s):

1. Return to the Register Map (0xF9)

	Addr: 0xFA	FIFO_MAP2			
Bit	Field	Reset	Туре	Bit Description	
7:5	Reserved	000			
4	FIFO_WRITE_FD_RESULT	0	R/W	<b>FIFO Write Flicker Detection Result.</b> If asserted, flicker detection on-chip calculation result is written to the FIFO Buffer.	
3	FIFO_WRITE_FD_DATA	0	R/W	<b>FIFO Write Flicker Detection Data.</b> If asserted, flicker detection data is written to the FIFO Buffer.	
2	FIFO_WRITE_PDATAR	0	R/W	<b>FIFO Write Proximity Ratio Data.</b> If asserted, proximity ratio data is written to the FIFO Buffer.	
1	FIFO_WRITE_PDATA1	0	R/W	<b>FIFO Write Proximity One Data.</b> If asserted, proximity one data is written to the FIFO Buffer.	
0	FIFO_WRITE_PDATA0	0	R/W	<b>FIFO Write Proximity Zero Data.</b> If asserted, proximity zero data is written to the FIFO Buffer.	

#### Note(s):

1. Return to the Register Map (0xFA)

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### FIFO Buffer Data and Status

The FIFO buffer is used to poll proximity or ALS data with fewer I<sup>2</sup>C read and write transactions. The FIFO buffer is 256 bytes of RAM. If the FIFO overflows (i.e. 129 datasets before host/system reads data from the FIFO buffer), an overflow flag will be set and new data will be lost. Host/Systems acquire data by reading addresses: 0xFC - 0xFF. The register address pointer automatically wraps from 0xFF to 0xFC as data are read. Data can be read one byte at a time or in blocks (there is no block-read length limit). When reading single bytes, the internal FIFO read pointer and the FIFO Buffer Level, FIFO\_LVL, are updated each time register 0xFF is read. For block-reads, the internal FIFO read pointer and the FIFO Buffer Level, FIFO\_LVL update for each two byte entry. If the FIFO continues to be accessed after FIFO\_LVL = 0, the device will return 0 for all data.

The FINT interrupt indicates when there is valid data in the FIFO buffer. The amount of unread data is indicated by the FIFO\_LVL.

Figure 92: FIFO\_STATUS

Ac	ldr: 0xFB	FIFO_STATUS		
Bit	Field	Reset	Туре	Bit Description
7	FIFO_OV	0	R	<b>FIFO Buffer Overflow.</b> Indicates that the FIFO buffer overflowed and information has been lost. Bit is automatically cleared when the FIFO buffer is read.
6:0	FIFO_LVL	0000000	R	<b>FIFO Buffer Level.</b> Indicates the number of entries (each are 4 bytes) available in the FIFO buffer waiting for readout. The FIFO RAM is 256byte (128 words) so the FIFO_LVL ranges from 0 entries to 64 entries.

#### Note(s):

1. Return to the Register Map (0xFB)

Figure 93: FDATA

Bits	Addr	Field	Reset	Туре	Description
7:0	0xFC	FDATA	0x00	R	
15:8	0xFD		0x00	R	FIFO Buffer Data
23:16	0xFE		0x00	R	
31:24	0xFF		0x00	R	

#### Note(s):

1. Return to the Register Map (0xFC, 0xFD, 0xFE, 0xFF)



### **Application Information**

Figure 94: TMD3719 Typical Application Circuit

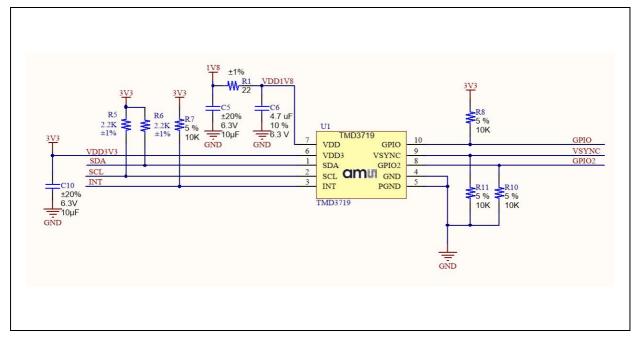
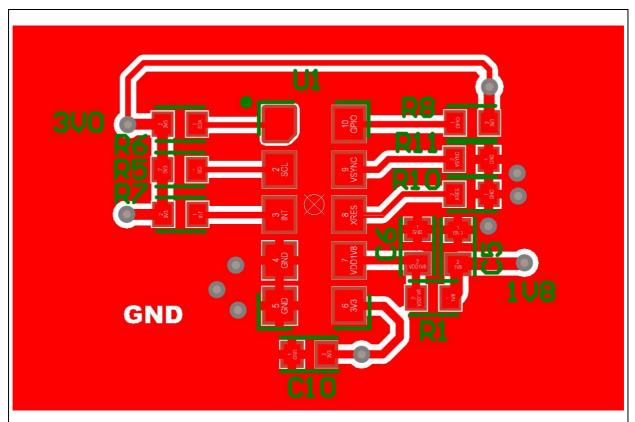


Figure 95: TMD3719 Recommended Circuit Layout

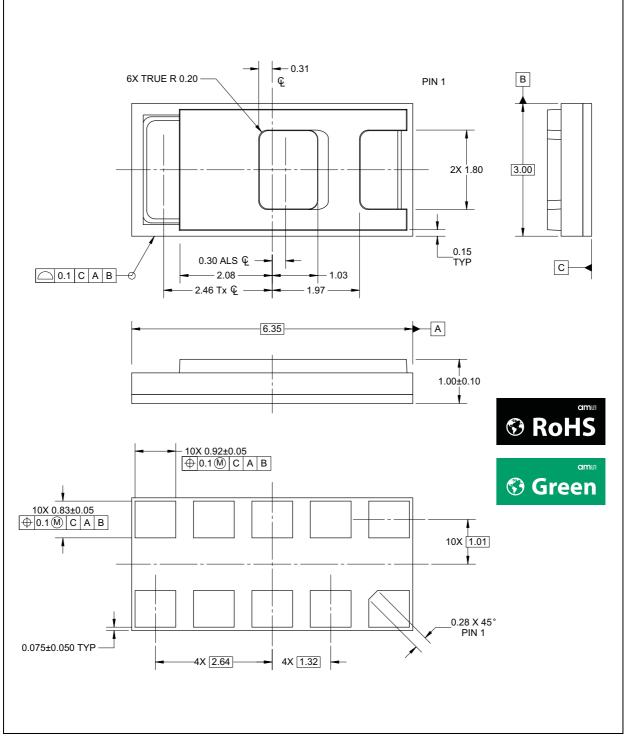




### Package Drawings & Markings

Figure 96:

TMD3719 Module Dimensions



#### Note(s):

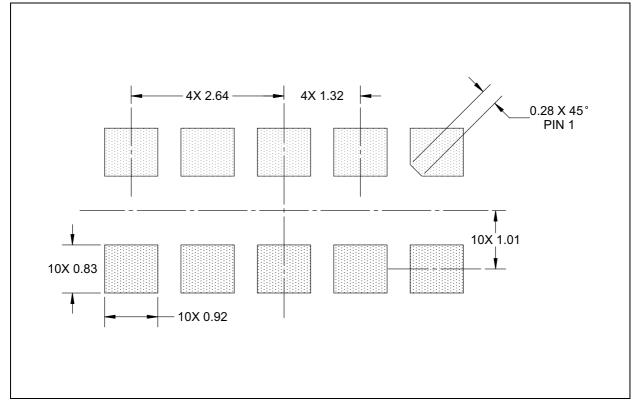
- 1. All linear dimensions are in millimeters.
- 2. Dimension tolerances are  $\pm 0.05$  mm unless otherwise noted.
- 3. Contacts are copper with NiPdAu plating.
- 4. This package contains no lead (Pb).
- 5. This drawing is subject to change without notice.
- 6. Measurement guarantee by lot acceptance testing using 20 units.



### **PCB Pad Layout**

Suggested PCB pad layout guidelines for the surface mount module are shown. Flash Gold is recommended as a surface finish for the landing pads.

### Figure 97: Recommended PCB Pad Layout



#### Note(s):

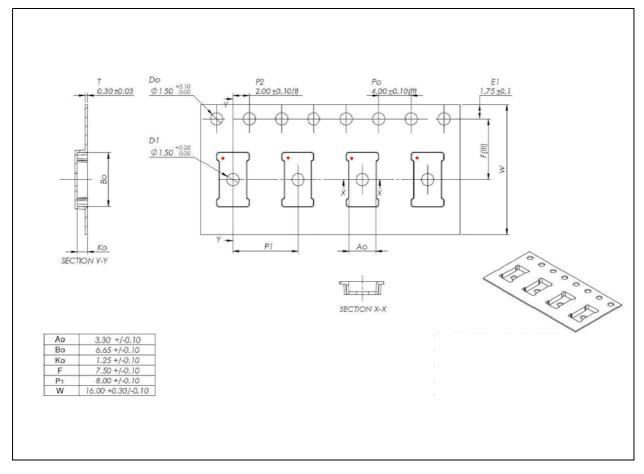
- 1. All linear dimensions are in millimeters.
- 2. Dimension tolerances are  $\pm 0.05 \text{mm}$  unless otherwise noted.
- 3. This drawing is subject to change without notice.



### **Tape & Reel Information**

Figure 98:

TMD3719 Tape and Reel Mechanical Drawing



#### Note(s):

1. All linear dimensions are in millimeters. Dimension tolerance is  $\pm$  0.10 mm unless otherwise noted.

2. The dimensions on this drawing are for illustrative purposes only. Dimensions of an actual carrier may vary slightly.

3. Symbols on drawing Ao, Bo, and Ko are defined in ANSI EIA Standard 481-B 2001.

4. Each reel is generally 330 millimeters in diameter and contains 10000 parts. Please reconfirm for actual orders.

5. ams packaging tape and reel conform to the requirements of EIA Standard 481-B.

6. In accordance with EIA standard, device pin 1 is located next to the sprocket holes in the tape.

7. This drawing is subject to change without notice.

### Soldering & Storage Information

### **Soldering Information**

The module has been tested and has demonstrated an ability to be reflow soldered to a PCB substrate. The solder reflow profile describes the expected maximum heat exposure of components during the solder reflow process of product on a PCB. Temperature is measured on top of component. The components should be limited to a maximum of three passes through this solder reflow profile.

Figure 99: Solder Reflow Profile

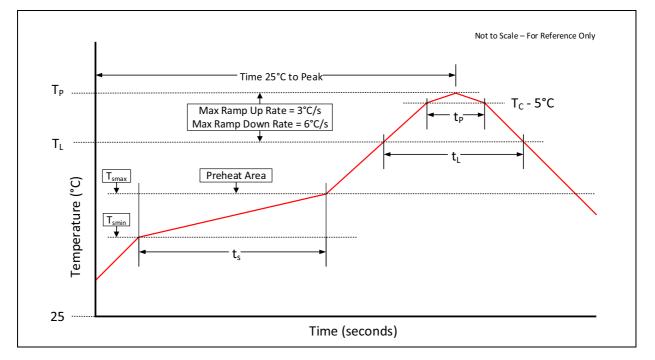
Profile Feature Preheat/ Soak	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Temperature Min (T <sub>smin</sub> )	100°C	150°C
Temperature Max (T <sub>smax</sub> )	150°C	200°C
Time $(t_s)$ from $(T_{smin} to T_{smax})$	60s - 120s	60s-120s
Ramp-up rate (T <sub>L</sub> to T <sub>P</sub> )	max. 3°C/s	max. 3°C/s
Liquidous temperature $(T_L)$ Time $(t_L)$ maintained above $T_L$	183°C 60s - 150s	217°C 60s - 150s
Peak package body temperature (T <sub>P</sub> )	For users T <sub>P</sub> must not exceed the Classification temp of 235°C. For suppliers T <sub>P</sub> must equal or exceed the Classification temp of 235°C.	For users $T_P$ must not exceed the Classification temp of 260°C. For suppliers $T_P$ must equal or exceed the Classification temp of 260°C.
Time $(t_P)^{(1)}$ within 5°C of the specified classification temperature $(T_c)$	20 <sup>(1)</sup> seconds	30 <sup>(1)</sup> seconds
Ramp-down rate (T <sub>P</sub> to T <sub>L</sub> )	Max. 6°C/s	Max. 6°C/s
Time 25°C to peak temperature	Max. 6 minutes	Max. 8 minutes

#### Note(s):

1. Tolerance for peak profile temperature (TP) is defined as a supplier minimum and a user maximum.



### Figure 100: Solder Reflow Profile Graph



### **Storage Information**

### **Moisture Sensitivity**

Optical characteristics of the device can be adversely affected during the soldering process by the release and vaporization of moisture that has been previously absorbed into the package.

To ensure the package contains the smallest amount of absorbed moisture possible, each device is baked prior to being dry packed for shipping. Devices are dry packed in a sealed aluminized envelope called a moisture-barrier bag with silica gel to protect them from ambient moisture during shipping, handling, and storage before use.

### Shelf Life

The calculated shelf life of the device in an unopened moisture barrier bag is 12 months from the date code on the bag when stored under the following conditions:

- Shelf Life: 12 months
- Ambient Temperature: <40°C
- Relative Humidity: <90%

Rebaking of the devices will be required if the devices exceed the 12 month shelf life or the Humidity Indicator Card shows that the devices were exposed to conditions beyond the allowable moisture region.



### Floor Life

The module has been assigned a moisture sensitivity level of MSL 3. As a result, the floor life of devices removed from the moisture barrier bag is 168 hours from the time the bag was opened, provided that the devices are stored under the following conditions:

- Floor Life: 168 hours
- Ambient Temperature: <30°C
- Relative Humidity: <60%

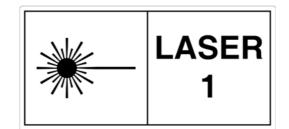
If the floor life or the temperature/humidity conditions have been exceeded, the devices must be rebaked prior to solder reflow or dry packing.

### **Rebaking Instructions**

When the shelf life or floor life limits have been exceeded, rebake at 50°C for 12 hours.

### Laser Eye Safety

The TMD3719 is designed to meet the Class 1 laser safety limits including single faults in compliance with IEC 60825-1:2014. This applied to the stand-alone device. In an end application system environment, the system may need to be tested to ensure it remains compliant. The system must not include any additional lens to concentrate the laser light or parameters set outside of the recommended operating conditions. Use outside of the recommended condition or any physical modification to the module during development could result in hazardous levels of radiation exposure.





### **Ordering & Contact Information**

Figure 101: Ordering Information

Ordering Code	Address	Interface	Delivery Form	Delivery Quantity
TMD37193	0x39	1.8V I <sup>2</sup> C	Tape & Reel	10000 pcs/reel

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### Headquarters

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### **Revision Information**

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Updated Figure 9 and notes below	10				
Updated Register Map (Status9)	18				
Updated Figure 59	55				
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#### Note(s):

1. Page and figure numbers for the previous version may differ from page and figure numbers in the current revision.

2. Correction of typographical errors is not explicitly mentioned.



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